

R9A02G015

R19DS0101EJ0100

Rev.1.00

Mar 29, 2019

ASSP (USB Power Delivery Controller)

1. OUTLINE

1.1 Features

Ultra-low power consumption technology

- V_{DD} = single power supply voltage of 2.7 to 5.5 V
- HALT mode
- STOP mode
- SNOOZE mode

RL78 CPU core

- CISC architecture with 3-stage pipeline
- Minimum instruction execution time: 0.04167 μ s:
@ 24 MHz operation with high-speed on-chip oscillator
- Multiply/divide/multiply & accumulate instructions are supported.
- Address space: 1 MB
- General-purpose registers: (8-bit register \times 8) \times 4 banks
- On-chip RAM: 7 KB

Code flash memory

- Code flash memory: 128 KB
- Block size: 1 KB
- Prohibition of block erase and rewriting (security function)
- On-chip debug function
- Self-programming (with boot swap function/flash shield window function)

Data flash memory

- Data flash memory: 2 KB
- Back ground operation (BGO): Instructions can be executed from the program memory while rewriting the data flash memory.
- Number of rewrites: 1,000,000 times (TYP.)
- Voltage of rewrites: V_{DD} = 2.7 to 5.5 V

High-speed on-chip oscillator

- Select from 48 MHz, 24 MHz, 16 MHz, 12 MHz, 8 MHz, 6 MHz, 4 MHz, 3 MHz, 2 MHz, and 1 MHz
- High accuracy: $\pm 1.0\%$ (V_{DD} = 2.7 to 5.5 V, T_A = -20 to +85°C)

Operating ambient temperature

- T_A = -40 to +85°C (A: Consumer applications)

Power management and reset function

- On-chip power-on-reset (POR) circuit
- On-chip voltage detector (LVD) (Select reset from 6 levels)

USB

- Complying with USB Specification Revision 2.0, incorporating host/function controller
- Corresponding to full-speed transfer (12 Mbps) and low-speed (1.5 Mbps)
- Complying with Battery Charging Specification Revision 1.2
- Compliant with the 2.1 A/1.0 A charging mode.

Serial interfaces

- CSI: 2 channels
- UART: 1 channel
- Simplified I²C: 2 channels
- I²C: 2 or 3 channels

Timers

- 16-bit timer: 8 channels
- 12-bit interval timer: 1 channel
- Watchdog timer: 1 channel

A/D converter

- 8/10-bit resolution A/D converter (V_{DD} = 2.7 to 5.5 V)
- Analog input: 8 channels
- Internal reference voltage (1.45 V) and temperature sensor

I/O ports

- I/O port: 23 or 28 (N-ch open drain I/O [withstand voltage of 6 V]: 5, N-ch open drain I/O [V_{DD} withstand voltage]: 8 or 13)
- Can be set to N-ch open drain, TTL input buffer, and on-chip pull-up resistor
- On-chip clock output/buzzer output controller

Others

- On-chip BCD (binary-coded decimal) correction circuit

Remark

The functions mounted depend on the product.
See 1.6 Outline of Functions.

ROM, RAM capacities

| Flash ROM | Data flash | RAM | R9A02G015 | |
|-----------|------------|----------------------|--------------------|-----------------------|
| | | | 32 pins (with USB) | 32 pins (without USB) |
| 128 KB | 2 KB | 7 KB ^{Note} | R9A02G0150 | R9A02G0151 |

Note The flash library uses RAM in self-programming and rewriting of the data flash memory.
The target products and start address of the RAM areas used by the flash library are shown below.

R9A02G0150/R9A02G0151: Start address FE300H

1.2 Ordering Information

Figure 1 - 1 Part Number and Package of R9A02G015

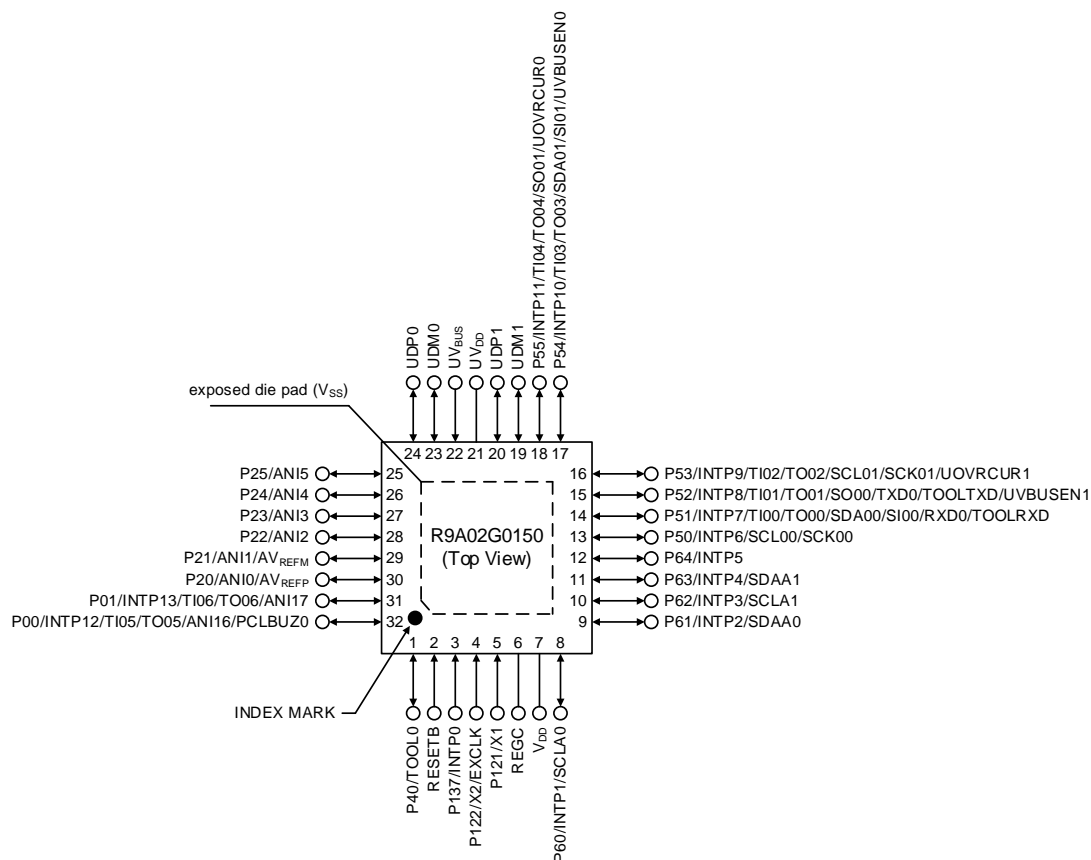
| Pin count | Package | Ordering Part Number | Remarks |
|-----------|--|----------------------|----------------------------------|
| 32 pins | 32-pin QFN (4 × 4 mm, 0.4 mm pitch) | R9A02G015020GNP#AC0 | Product with USB (R9A02G0150) |
| | | R9A02G015120GNP#AC0 | Product without USB (R9A02G0151) |

Caution The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

1.3 Pin Configuration (Top View)

1.3.1 32-pin product (with USB)

- 32-pin QFN (4 × 4 mm, 0.4 mm pitch)



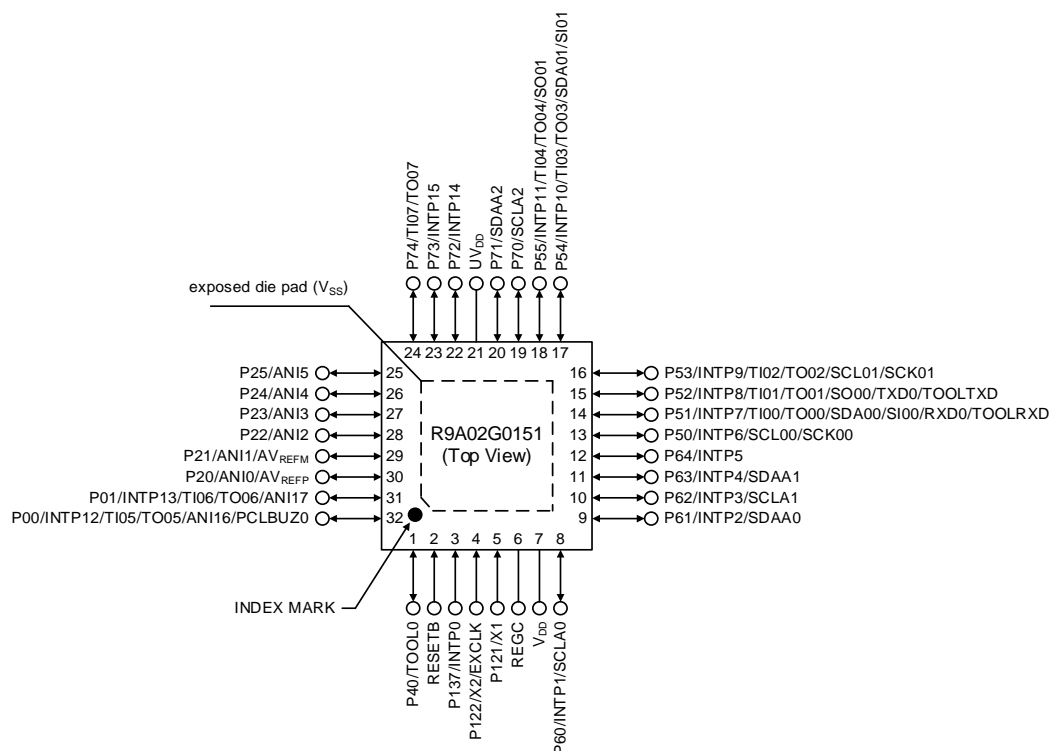
Caution 1. Connect the exposed die pad (V_{SS}) to ground.

Caution 2. Connect the REGC pin to V_{SS} via a capacitor (0.47 to 1 μ F).

Remark For pin identification, see 1.4 Pin Identification.

1.3.2 32-pin product (without USB)

- 32-pin QFN (4 × 4 mm, 0.4 mm pitch)



Caution 1. Connect the exposed die pad (V_{SS}) to ground.

Caution 2. Connect the REGC pin to V_{SS} via a capacitor (0.47 to 1 μF).

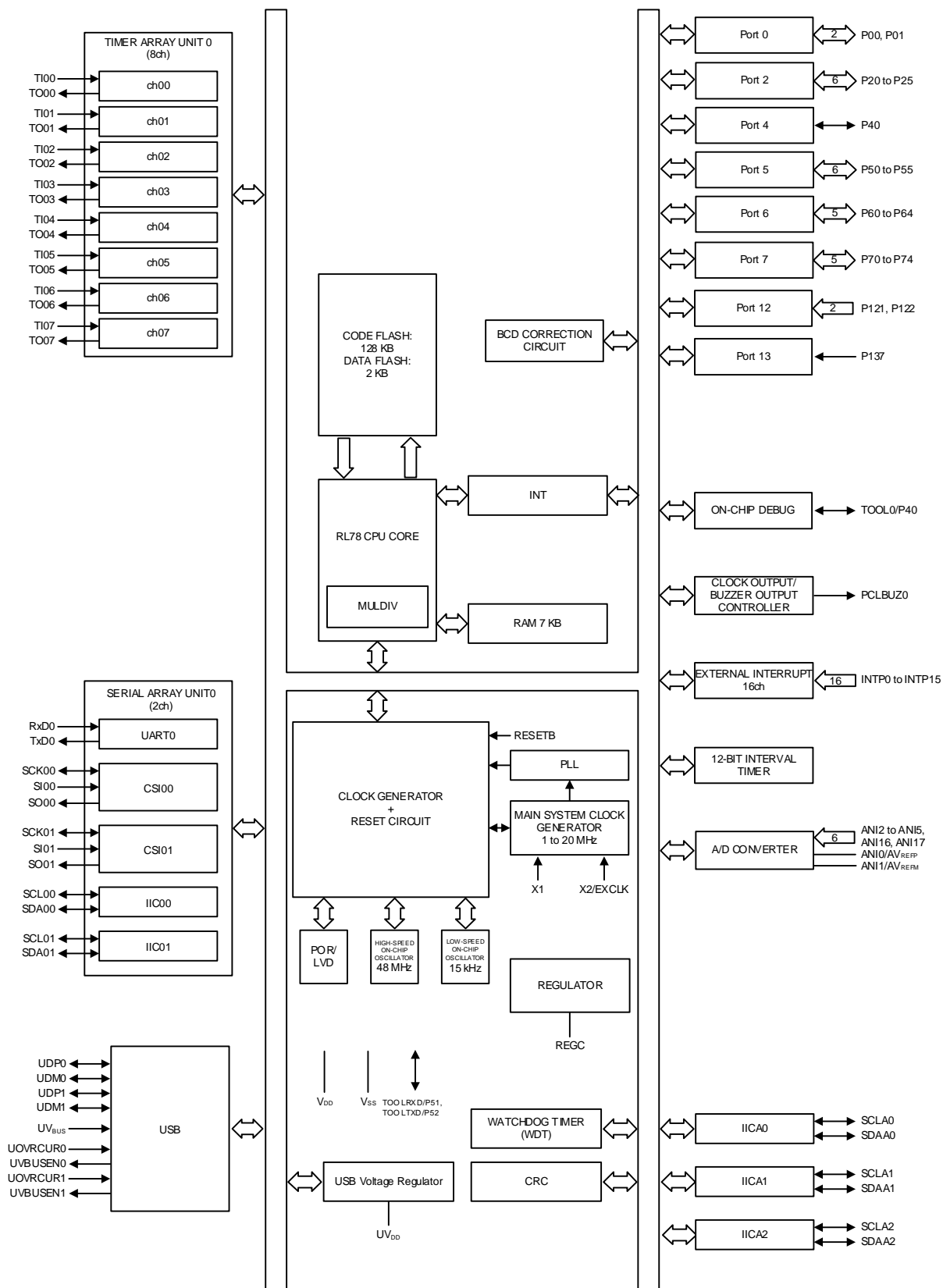
Remark For pin identification, see 1.4 Pin Identification.

1.4 Pin Identification

| | |
|-------------------------------|--|
| ANI0 to ANI5, ANI16, ANI17: | Analog input |
| AV _{REFM} : | A/D converter reference potential (- side) input |
| AV _{REFP} : | A/D converter reference potential (+ side) input |
| EXCLK: | External clock input (main system clock) |
| INTP0 to INTP15: | External interrupt input |
| P00, P01: | Port 0 |
| P20 to P25: | Port 2 |
| P40: | Port 4 |
| P50 to P55: | Port 5 |
| P60 to P64: | Port 6 |
| P70 to P74: | Port 7 |
| P121, P122: | Port 12 |
| P137: | Port 13 |
| PCLBUZ0: | Programmable clock output/buzzer output |
| REGC: | Regulator capacitance |
| RESETB: | Reset |
| RxD0: | Receive data |
| SCK00, SCK01: | Serial clock input/output |
| SCLA0 to SCLA2, SCL00, SCL01: | Serial clock input/output |
| SDAA0 to SDAA2, SDA00, SDA01: | Serial data input/output |
| SI00, SI01: | Serial data input |
| SO00, SO01: | Serial data output |
| TI00 to TI07: | Timer input |
| TO00 to TO07: | Timer output |
| TOOL0: | Data input/output for tool |
| TOOLRXD, TOOLTXD: | Data input/output for external device |
| TxD0: | Transmit data |
| UDM0, UDM1, UDP0, UDP1: | USB Input/Output |
| UOVRCUR0, UOVRCUR1: | USB Input |
| UVBUSEN0, UVBUSEN1: | USB Output |
| UV _{DD} : | USB Power Supply/USB Regulator Capacitance |
| UV _{BUS} : | USB Input/USB Power Supply (USB Optional BC) |
| V _{DD} : | Power supply |
| V _{SS} : | Ground |
| X1, X2: | Crystal oscillator (main system clock) |

1.5 Block Diagram

1.5.1 32-pin products



1.6 Outline of Functions

(1/2)

| Item | | 32-pin (with USB) | 32-pin (without USB) |
|------------------------------------|--|--|----------------------|
| | | R9A02G0150 | R9A02G0151 |
| Code flash memory (KB) | | 128 KB | |
| Data flash memory (KB) | | 2 KB | |
| RAM | | 7KB ^{Note 1} | |
| Address space | | 1 MB | |
| Main system clock | High-speed system clock (f_{MX}) | X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (High-speed main) mode: 1 to 20 MHz ($V_{DD} = 2.7$ to 5.5 V) | |
| | High-speed on-chip oscillator clock (f_{IH}) Max: 24 MHz | HS (High-speed main) mode: 1 to 24 MHz ($V_{DD} = 2.7$ to 5.5 V) | |
| | PLL clock | 6, 12, 24 MHz ^{Note 2} : $V_{DD} = 2.7$ to 5.5 V | |
| Subsystem clock | Low-speed on-chip oscillator clock (f_{IL}) | 15 kHz (TYP.): $V_{DD} = 2.7$ to 5.5 V | |
| General-purpose register | | 8 bits × 32 registers (8 bits × 8 registers × 4 banks) | |
| Minimum instruction execution time | | 0.04167 μ s (High-speed on-chip oscillator clock: $f_{HOCO} = 48\text{MHz}/f_{IH} = 24$ MHz operation) | |
| | | 0.04167 μ s (PLL clock: $f_{PLL} = 48$ MHz/ $f_{IH} = 24$ MHz ^{Note 2} operation) | |
| | | 0.05 μ s (High-speed system clock: $f_{MX} = 20$ MHz operation) | |
| Instruction set | | <ul style="list-style-type: none"> • Data transfer (8/16 bits) • Adder and subtractor/logical operation (8/16 bits) • Multiplication (8 bits × 8 bits, 16 bits × 16 bits), Division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits) • Multiplication and Accumulation (16 bits × 16 bits + 32 bits) • Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc. | |
| I/O port | Total | 23 | 28 |
| | CMOS I/O | 15 | 20 |
| | CMOS input | 3 | |
| | N-ch open-drain I/O (6 V tolerance) | 5 | |
| Timer | 16-bit timer | 8 channels | |
| | Watchdog timer | 1 channel | |
| | 12-bit interval timer | 1 channel | |
| | Timer output | 7 | 8 |
| Clock output/buzzer output | | 1 | |
| | | 2.93 kHz, 5.86 kHz, 11.7 kHz, 1.5 MHz, 3 MHz, 6 MHz (Main system clock: $f_{MAIN} = 24$ MHz operation) | |
| 10-bit resolution A/D converter | | 8 channels | |
| Serial interface | | CSI: 2 channels/UART: 1 channel/simplified I ² C: 2 channels | |
| | I ² C bus | 2 channels | 3 channels |

(2/2)

| Item | | 32-pin (with USB) | 32-pin (without USB) |
|-------------------------------|---------------------|---|----------------------|
| | | R9A02G0150 | R9A02G0151 |
| USB | Host controller | 2 channels | — |
| | Function controller | 1 channel | — |
| Vectored interrupt sources | Internal | 22 | 21 |
| | External | 14 | 16 |
| Reset | | <ul style="list-style-type: none"> Reset by RESETB pin Internal reset by watchdog timer Internal reset by power-on-reset Internal reset by voltage detector Internal reset by illegal instruction execution ^{Note 3} Internal reset by RAM parity error Internal reset by illegal-memory access | |
| Power-on-reset circuit | | <ul style="list-style-type: none"> Power-on-reset: 1.51 ± 0.04 V ($T_A = -40$ to $+85^\circ\text{C}$) Power-down-reset: 1.50 ± 0.04 V ($T_A = -40$ to $+85^\circ\text{C}$) | |
| Voltage detector | Power on | 2.81 V to 4.06 V (6 stages) | |
| | Power down | 2.75 V to 3.98 V (6 stages) | |
| On-chip debug function | | Provided (Enable to tracing) | |
| Power supply voltage | | $V_{DD} = 2.7$ to 5.5 V | |
| Operating ambient temperature | | $T_A = -40$ to $+85^\circ\text{C}$ | |

Note 1. The flash library uses RAM in self-programming and rewriting of the data flash memory.
The target products and start address of the RAM areas used by the flash library are shown below.

R9A02G0150/R9A02G0151: Start address FE300H

Note 2. In the PLL clock 48 MHz operation, the system clock is 2/4/8 dividing ratio.

Note 3. The illegal instruction is generated when instruction code FFH is executed.
Reset by the illegal instruction execution is not issued by emulation with the in-circuit emulator or on-chip debug emulator.

2. ELECTRICAL SPECIFICATIONS

The target products A: Consumer applications; T_A = -40 to +85°C
R9A02G0150, R9A02G0151

- Cautions**
1. The R9A02G015 has an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.
 2. The pins mounted depend on the product. Refer to 2.1 Port Function to 2.2 Functions other than port pins in the R9A02G015 User's Manual.

2.1 Absolute Maximum Ratings

Absolute Maximum Ratings (T_A = 25°C) (1/2)

| Parameter | Symbols | Conditions | Ratings | Unit |
|------------------------------------|--------------------|---|--|------|
| Supply voltage | V _{DD} | | −0.5 to +6.5 | V |
| REGC pin input voltage | V _{IREGC} | REGC | −0.3 to +2.8 and −0.3 to V _{DD} +0.3 ^{Note 1} | V |
| UV _{DD} pin input voltage | V _{IUVDD} | UV _{DD} | −0.3 to V _{DD} +0.3 | V |
| Input voltage | V _{I1} | P00, P01, P20 to P25, P40, P50 to P55, P70 to P74, P121, P122, P137, RESETB | −0.3 to V _{DD} +0.3 ^{Note 2} | V |
| | V _{I2} | P60 to P64 (N-ch open-drain) | −0.3 to +6.5 | V |
| | V _{I3} | UDP0, UDM0, UDP1, UDM1 | −0.3 to +6.5 | V |
| | V _{I4} | UV _{BUS} | −0.3 to +6.5 | V |
| Output voltage | V _{O1} | P00, P01, P20 to P25, P40, P50 to P55, P70 to P74 | −0.3 to V _{DD} +0.3 ^{Note 2} | V |
| | V _{O2} | UDP0, UDM0, UDP1, UDM1 | −0.3 to +6.5 | V |
| Analog input voltage | V _{AI1} | ANI16, ANI17 | −0.3 to V _{DD} +0.3 and −0.3 to AV _{REF} (+) +0.3 Notes 2, 3 | V |
| | V _{AI2} | ANI0 to ANI5 | −0.3 to V _{DD} +0.3 and −0.3 to AV _{REF} (+) +0.3 Notes 2, 3 | V |

- Notes**
1. Connect the REGC pin to V_{SS} via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.
 2. Must be 6.5 V or lower.
 3. Do not exceed AV_{REF}(+) + 0.3 V in case of A/D conversion target pin

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

- Remarks**
1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.
 2. AV_{REF} (+) : The + side reference voltage of the A/D converter. This can be selected from AV_{REFP}, the internal reference voltage (1.45 V), and V_{DD}.
 3. V_{SS} : Reference voltage

Absolute Maximum Ratings (T_A = 25°C) (2/2)

| Parameter | Symbols | Conditions | | Ratings | Unit |
|-------------------------------|------------------|----------------------------------|---|-------------|------|
| Output current, high | I _{OH1} | Per pin | P00, P01, P40, P50 to P55, P70-P74 | −40 | mA |
| | | Total of all pins −170 mA | P00, P01, P40 | −70 | mA |
| | | | P50 to P55, P70 to P74 | −100 | mA |
| | I _{OH2} | Per pin | P20 to P25 | −0.5 | mA |
| | | Total of all pins | | −2 | mA |
| Output current, low | I _{OL1} | Per pin | P00, P01, P40, P50 to P55, P60 to P64, P70 to P74 | 40 | mA |
| | | Total of all pins 170 mA | P00, P01, P40 | 70 | mA |
| | | | P50 to P55, P60 to P64, P70 to P74 | 100 | mA |
| | I _{OL2} | Per pin | P20 to P25 | 1 | mA |
| | | Total of all pins | | 5 | mA |
| Operating ambient temperature | T _A | In normal operation mode | | −40 to +85 | °C |
| | | In flash memory programming mode | | | |
| Storage temperature | T _{stg} | | | −65 to +150 | °C |

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

2.2 Oscillator Characteristics

2.2.1 X1 oscillator characteristics

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Parameter | Resonator | Conditions | MIN. | TYP. | MAX. | Unit |
|--|---|--|------|------|------|------|
| X1 clock oscillation frequency (f_x) ^{Note} | Ceramic resonator/ crystal resonator | $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | 1.0 | | 20.0 | MHz |

Note Indicates only permissible oscillator frequency ranges. Refer to AC Characteristics for instruction execution time. Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

Caution Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

2.2.2 On-chip oscillator characteristics

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Oscillators | Parameters | Conditions | MIN. | TYP. | MAX. | Unit |
|---|------------|------------------------------|--------|------|--------|------|
| High-speed on-chip oscillator clock frequency ^{Notes 1, 2} | f_{HOCO} | | 1 | | 48 | MHz |
| High-speed on-chip oscillator clock frequency accuracy | | -20 to $+85^\circ\text{C}$ | -1.0 | | $+1.0$ | % |
| | | -40 to -20°C | -1.5 | | $+1.5$ | % |
| Low-speed on-chip oscillator clock frequency | f_{IL} | | | 15 | | kHz |
| Low-speed on-chip oscillator clock frequency accuracy | | | -15 | | $+15$ | % |

Notes 1. High-speed on-chip oscillator frequency is selected by bits 0 to 3 of option byte (000C2H/010C2H) and bits 0 to 2 of HOCODIV register.

2. This indicates the oscillator characteristics only. Refer to AC Characteristics for instruction execution time.

2.2.3 PLL oscillator characteristics

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Oscillators | Parameters | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------------------|-------------|-------------------------|------|-------|-------|------|
| PLL input frequency ^{Note} | f_{PLLIN} | High-speed system clock | 6.00 | | 16.00 | MHz |
| PLL output frequency ^{Note} | f_{PLL} | | | 48.00 | | MHz |

Note Indicates only oscillator characteristics. Refer to AC Characteristics for instruction execution time.

2.3 DC Characteristics

2.3.1 Pin characteristics

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Items | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|------------------------|-----------|---------------------------------------|--|-------------|------|-------------|------|
| Input voltage, high | V_{IH1} | P00, P01, P40, P50 to P55, P70 to P74 | Normal input buffer | $0.8V_{DD}$ | | V_{DD} | V |
| | V_{IH2} | P00, P01, P50 to P55, P70 to P74 | TTL input buffer $4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | 2.2 | | V_{DD} | V |
| | | | TTL input buffer $3.3\text{ V} \leq V_{DD} < 4.0\text{ V}$ | 2.0 | | V_{DD} | V |
| | | | TTL input buffer $2.7\text{ V} \leq V_{DD} < 3.3\text{ V}$ | 1.5 | | V_{DD} | V |
| | V_{IH3} | P20 to P25 | | $0.7V_{DD}$ | | V_{DD} | V |
| | V_{IH4} | P60 to P64 | | $0.7V_{DD}$ | | 6.0 | V |
| | V_{IH5} | P121, P122, P137, RESETB | | $0.8V_{DD}$ | | V_{DD} | V |
| Input voltage, low | V_{IL1} | P00, P01, P40, P50 to P55, P70 to P74 | Normal input buffer | 0 | | $0.2V_{DD}$ | V |
| | V_{IL2} | P00, P01, P50 to P55, P70 to P74 | TTL input buffer $4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | 0 | | 0.8 | V |
| | | | TTL input buffer $3.3\text{ V} \leq V_{DD} < 4.0\text{ V}$ | 0 | | 0.5 | V |
| | | | TTL input buffer $2.7\text{ V} \leq V_{DD} < 3.3\text{ V}$ | 0 | | 0.32 | V |
| | V_{IL3} | P20 to P25 | | 0 | | $0.3V_{DD}$ | V |
| | V_{IL4} | P60 to P64 | | 0 | | $0.3V_{DD}$ | V |
| | V_{IL5} | P121, P122, P137, RESETB | | 0 | | $0.2V_{DD}$ | V |

Caution The maximum value of V_{IH} of pins P00, P01, P50-P55, and P70-P74 is V_{DD} , even in the N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Items | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------|------------------|---------------------------------------|--|-----------------------|------|------|
| Output voltage, high | V _{OH1} | P00, P01, P40, P50 to P55, P70 to P74 | 2.7 V ≤ V _{DD} ≤ 5.5 V, I _{OH1} = -1.5 mA | V _{DD} - 0.5 | | V |
| | V _{OH2} | P20 to P25 | 2.7 V ≤ V _{DD} ≤ 5.5 V, I _{OH2} = -100 μA | V _{DD} - 0.5 | | V |
| Output voltage, low | V _{OL1} | P00, P01, P40, P50 to P55, P70 to P74 | 2.7 V ≤ V _{DD} ≤ 5.5 V, I _{OL1} = 1.5 mA | | 0.4 | V |
| | V _{OL2} | P20 to P25 | 2.7 V ≤ V _{DD} ≤ 5.5 V, I _{OL2} = 400 μA | | 0.4 | V |
| | V _{OL3} | P60 to P64 | 2.7 V ≤ V _{DD} ≤ 5.5 V, I _{OL1} = 3.0 mA | | 0.4 | V |

Caution P00, P01, P50-P55, and P70-P74 do not output high level in N-ch open-drain mode.**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Items | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|-----------------------------|-------------------|---|--|---------------------------------------|------|------|-----------|
| Input leakage current, high | I _{LIH1} | P00, P01, P20 to P25, P40, P50 to P55, P60 to P64, P70 to P74, P137, RESETB | V _I = V _{DD} | | | | 1 μA |
| | I _{LIH2} | P121, P122 | V _I = V _{DD} | In input port or external clock input | | | 1 μA |
| Input leakage current, low | I _{LIL1} | P00, P01, P20 to P25, P40, P50 to P55, P60 to P64, P70 to P74, P137, RESETB | V _I = V _{SS} | | | | −1 μA |
| | I _{LIL2} | P121, P122 | V _I = V _{SS} | In input port or external clock input | | | −1 μA |
| On-chip pll-up resistance | R _U | P00, P01, P40, P50 to P55, P70 to P74 | V _I = V _{SS} , In input port | | 10 | 20 | 100 kΩ |

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

2.3.2 Supply current characteristics

(T_A = 25 °C, V_{DD} = 3.3 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--------------------------|-------------------------|----------------|---------------------------|---|------|------|------|
| Supply current Note 1 | I _{DD1} | Operating mode | HS (High-speed main) mode | f _{HOCO} = 48 MHz f _{IH} = 24 MHz Note 2 | | 2.8 | mA |
| | | | | f _{HOCO} = 24 MHz f _{IH} = 24 MHz Note 2 | | 2.6 | mA |
| | I _{DD2} Note 3 | HALT mode | HS (High-speed main) mode | f _{HOCO} = 48 MHz f _{IH} = 24 MHz Note 4 | | 0.92 | mA |
| | | | | f _{HOCO} = 24 MHz f _{IH} = 24 MHz Note 4 | | 0.72 | mA |
| | I _{DD3} Note 5 | STOP mode | | | | 0.26 | μA |
| | | | | | | | |

- Notes**
1. Total current flowing into V_{DD}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD}, or V_{SS}. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
 2. When high-speed system clock is stopped.
 3. During HALT instruction execution by flash memory.
 4. When high-speed system clock and Low-speed on-chip oscillator clock are stopped.
 5. Not including the current flowing into the 12-bit interval timer and watchdog timer.

Remarks 1. f_{HOCO}: High-speed on-chip oscillator clock frequency (Max. 48 MHz)

2. f_{IH}: Main system clock source frequency obtained by dividing the high-speed on-chip oscillator clock by 2, 4, or 8 (Max. 24 MHz)

(T_A = 25 °C, V_{DD} = UV_{DD} = 3.3 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--|---|------|------|------|------|
| USB operating current ^{Note 1} | I _{USBF} ^{Note 2} | During USB communication operation under the following settings and conditions: <ul style="list-style-type: none"> • The function controller is set to operate in full-speed mode • The internal power supply for the USB is stopped. • f_{HOCO} = 48MHz, f_{IH} = 24MHz | | 1.8 | | mA |
| | I _{SUSP} ^{Note 3} | During suspended state under the following settings and conditions: <ul style="list-style-type: none"> • The function controller is set to full-speed mode (the UDP0 pin is pulled up). • The internal power supply for the USB is stopped. • The system is set to STOP mode (When the high-speed on-chip oscillator and high-speed system clock are stopped. When the watchdog timer is stopped.). | | 180 | | μA |

Notes 1. Current flowing into V_{DD} and UV_{DD}.

2. Current consumed only by the USB module.

3. Includes the current supplied from the pull-up resistor of the UDP0 pin to the pull-down resistor of the host device, in addition to the current consumed by this MCU during the suspended state.

Remarks 1. f_{HOCO}: High-speed on-chip oscillator clock frequency (Max. 48 MHz)2. f_{IH}: Main system clock source frequency obtained by dividing the high-speed on-chip oscillator clock by 2, 4, or 8 (Max. 24 MHz)

2.4 AC Characteristics

2.4.1 Basic operation

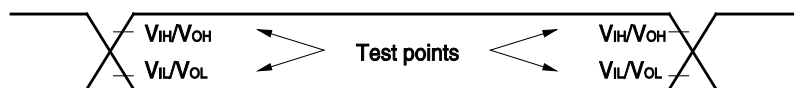
($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Items | Symbol | Conditions | | | MIN. | TYP. | MAX. | Unit |
|---|---------------------------------------|--|---------------------------------|---------------------------------|---------|------|------|------|
| Instruction cycle (minimum instruction execution time) | T _{CY} | Main system clock (f _{MAIN}) operation | HS (High-speed main) mode | 2.7 V ≤ V _{DD} ≤ 5.5 V | 0.04167 | | 1 | μs |
| | | In the self programming mode | HS (High-speed main) mode | 2.7 V ≤ V _{DD} ≤ 5.5 V | 0.04167 | | 1 | μs |
| External system clock frequency | f _{EX} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | | 1.0 | | 20.0 | MHz |
| External system clock input high-level width, low-level width | t _{EXH} , t _{EXL} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | | 24 | | | ns |
| Interrupt input high-level width, low-level width | t _{INTH} , t _{INTL} | INTP0 to INTP15 | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 1 | | | μs |
| RESETB low-level width | tr _{SL} | | | | 10 | | | μs |

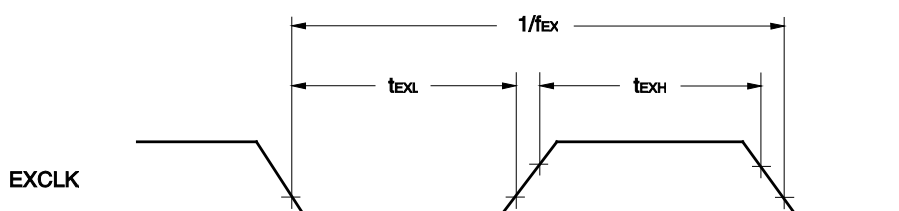
Remark f_{MCK} : Timer array unit operation clock frequency

(Operation clock to be set by the CKS0n bit of timer mode register 0n (TMR0n). n: Channel number (n = 0 to 7))

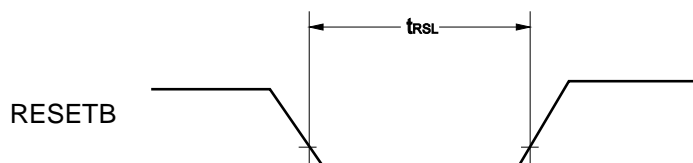
AC Timing Test Points



External System Clock Timing



RESETB Input Timing



2.5 Peripheral Functions Characteristics

2.5.1 Serial array unit

(1) During communication at same potential (UART mode) (dedicated baud rate generator output)

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

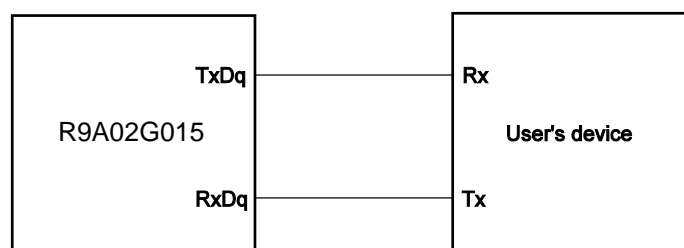
| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------|--------|---|------|------|-------------|------|
| Transfer rate | | | | | $f_{MCK}/6$ | bps |
| | | Theoretical value of the maximum transfer rate $f_{MCK} = f_{CLK}$ ^{Note} | | | 4.0 | Mbps |

Note The maximum operating frequencies of the CPU/peripheral hardware clock (f_{CLK}) are:

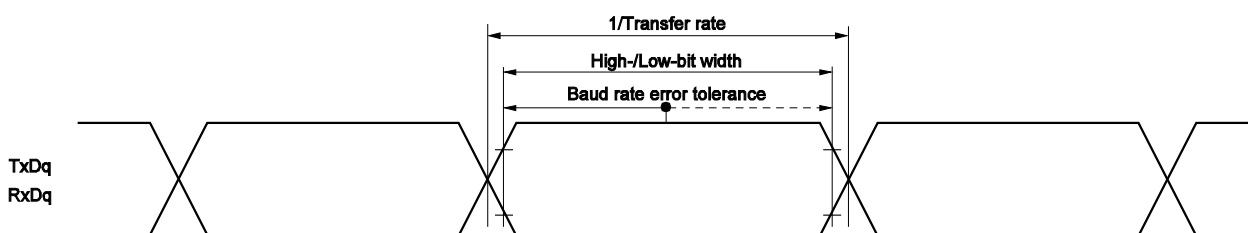
HS (high-speed main) mode: 24 MHz ($2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$)

Caution Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

UART mode connection diagram (during communication at same potential)



UART mode bit width (during communication at same potential) (reference)



- Remarks**
1. q: UART number ($q = 0$), g: PIM and POM number ($g = 5$)
 2. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number ($mn = 00$))

(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only)

(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--|--|---------------------------|------|------|------|
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 2/f _{CLK} 2.7 V ≤ V _{DD} ≤ 5.5 V | 83.3 | | | ns |
| SCKp high-/low-level width | t _{KH1} , t _{KL1} | 4.0 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 7 | | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 10 | | | ns |
| Slp setup time (to SCKp↑) ^{Note 1} | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V | 23 | | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 33 | | | ns |
| Slp hold time (from SCKp↑) ^{Note 2} | t _{SIH1} | 2.7 V ≤ V _{DD} ≤ 5.5 V | 10 | | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 3} | t _{KSO1} | C = 20 pF ^{Note 4} | | | 10 | ns |

- Notes**
1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 4. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks**
1. This specification is valid only when CSI00's peripheral I/O redirect function is not used.
 2. p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0),
g: PIM and POM numbers (g = 5)
 3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

(3) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--------------------|--|---------------------------|------|------|------|
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 4/f _{CLK} 2.7 V ≤ V _{DD} ≤ 5.5 V | 167 | | | ns |
| SCKp high-/low-level width | t _{KH1} , | 4.0 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 12 | | | ns |
| | t _{KL1} | 2.7 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 18 | | | ns |
| Slp setup time (to SCKp↑) ^{Note 1} | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V | 44 | | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 44 | | | ns |
| Slp hold time (from SCKp↑) ^{Note 2} | t _{KSI1} | | 19 | | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 3} | t _{KSO1} | C = 30 pF ^{Note 4} | | | 25 | ns |

- Notes**
1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 4. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks**
1. p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1),
g: PIM and POM numbers (g = 5)
 2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKS_{mn} bit of serial mode register mn (SMR_{mn}). m: Unit number,
n: Channel number (mn = 00, 01))

(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)**(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)**

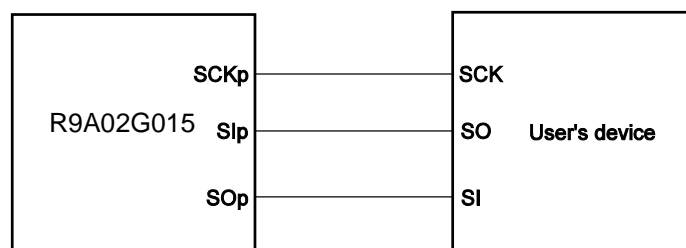
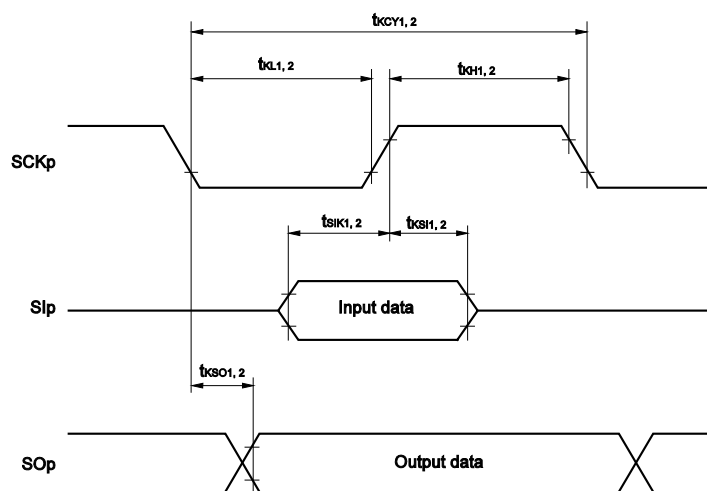
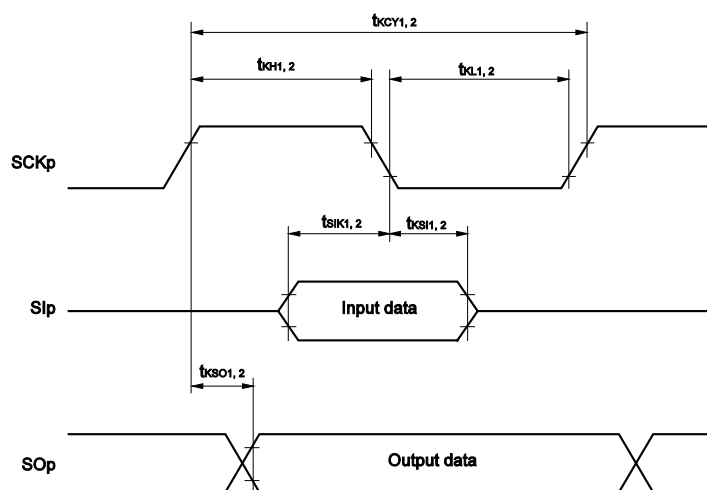
| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|--------------------|---------------------------------|---------------------------------|--------------------------|------|------------------------|------|
| SCKp cycle time ^{Note 5} | t _{KCY2} | 4.0 V ≤ V _{DD} ≤ 5.5 V | 20 MHz < f _{MCK} | 8/f _{MCK} | | | ns |
| | | | f _{MCK} ≤ 20 MHz | 6/f _{MCK} | | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 16 MHz < f _{MCK} | 8/f _{MCK} | | | ns |
| | | | f _{MCK} ≤ 16 MHz | 6/f _{MCK} | | | ns |
| SCKp high-/low-level width | t _{KH2} , | 4.0 V ≤ V _{DD} ≤ 5.5 V | | t _{KCY2} /2 - 7 | | | ns |
| | t _{KL2} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | t _{KCY2} /2 - 8 | | | ns |
| Slp setup time (to SCKp↑) ^{Note 1} | t _{SIK2} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 1/f _{MCK} +20 | | | ns |
| Slp hold time (from SCKp↑) ^{Note 2} | t _{SLI2} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 1/f _{MCK} +31 | | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 3} | t _{KSO2} | C = 30 pF ^{Note 4} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | | 2/f _{MCK} +44 | ns |

- Notes**
1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 4. C is the load capacitance of the SOp output lines.
 5. Transfer rate in the SNOOZE mode : MAX. 1 Mbps

Caution Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks**
1. p: CSI number (p = 00, 01), m: Unit number (m = 0),
n: Channel number (n = 0, 1), g: PIM number (g = 0, 5, 7)
 2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,
n: Channel number (mn = 00, 01))

CSI mode connection diagram (during communication at same potential)


 CSI mode serial transfer timing (during communication at same potential)
 (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)

 CSI mode serial transfer timing (during communication at same potential)
 (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)


- Remarks**
1. p: CSI number (p = 00, 01)
 2. m: Unit number, n: Channel number (mn = 00, 01)

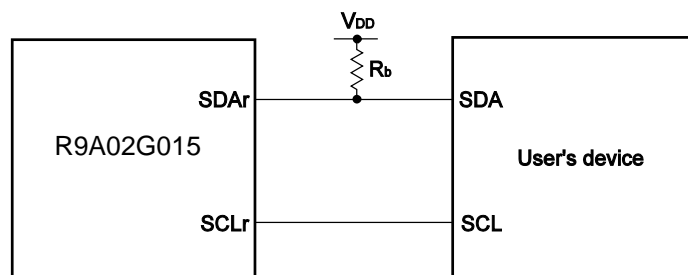
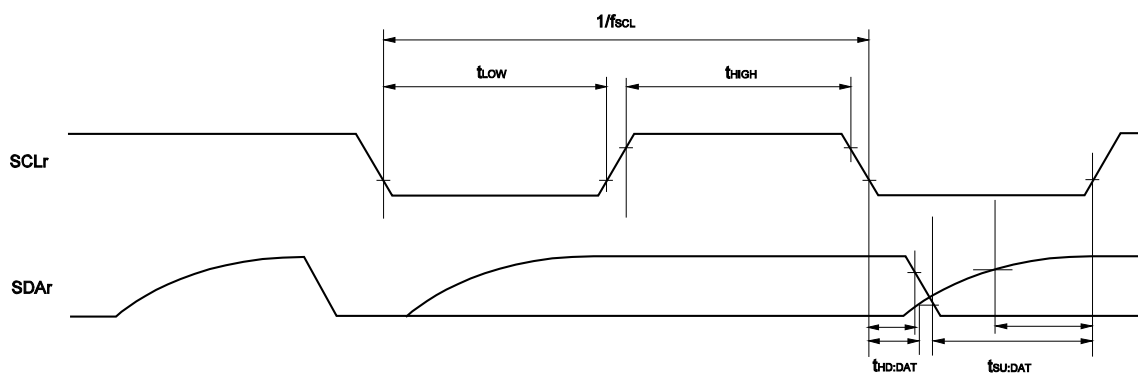
(5) During communication at same potential (simplified I²C mode)(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|-------------------------------|---------------------|---|--|------------------------|------|
| SCLr clock frequency | f _{SCL} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | | 1000 ^{Note 1} | kHz |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | | 400 ^{Note 1} | kHz |
| Hold time when SCLr = "L" | t _{LOW} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 475 | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 1150 | | ns |
| Hold time when SCLr = "H" | t _{HIGH} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 475 | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 1150 | | ns |
| Data setup time (reception) | t _{SU-DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 85 ^{Note 2} | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 1/f _{MCK} + 145 ^{Note 2} | | ns |
| Data hold time (transmission) | t _{HD-DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 0 | 305 | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 0 | 355 | ns |

Notes 1. The value must also be equal to or less than f_{MCK}/4.2. Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the normal input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Caution and Remarks are listed on the next page.)

Simplified I²C mode connection diagram (during communication at same potential)Simplified I²C mode serial transfer timing (during communication at same potential)

- Remarks**
1. $R_b[\Omega]$: Communication line (SDAr) pull-up resistance, $C_b[F]$: Communication line (SDAr, SCLr) load capacitance
 2. r: IIC number (r = 00, 01), g: PIM number (g = 5), h: POM number (h = 5)
 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0), n: Channel number (n = 0, 1), mn = 00, 01)

(6) Communication at different potential (2.5 V, 3 V) (UART mode) (1/2)**(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)**

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|---------------|--------|------------|---|------|------|---------------------------------------|------|
| Transfer rate | | reception | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | | | f _{MCK} /6 ^{Note 1} | bps |
| | | | Theoretical value of the maximum transfer rate f _{MCK} = f _{CLK} ^{Note 2} | | | 4.0 | Mbps |
| | | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | | | f _{MCK} /6 ^{Note 1} | bps |
| | | | Theoretical value of the maximum transfer rate f _{MCK} = f _{CLK} ^{Note 2} | | | 4.0 | Mbps |

Notes 1. Use it with V_{DD} ≥ V_b.**2.** The maximum operating frequencies of the CPU/peripheral hardware clock (f_{CLK}) are:HS (high-speed main) mode: 24 MHz (2.7 V ≤ V_{DD} ≤ 5.5 V)

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V_{DD} tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

Remarks 1. V_b[V]: Communication line voltage**2.** q: UART number (q = 0), g: PIM and POM number (g = 5)

3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

(6) Communication at different potential (2.5 V, 3 V) (UART mode) (2/2)

(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|---------------|--------|--------------|----------------------------------|------|------|-------------------|------|
| Transfer rate | | transmission | 4.0 V ≤ V _{DD} ≤ 5.5 V, | | | Note 1 | bps |
| | | | 2.7 V ≤ V _b ≤ 4.0 V | | | 2.8 Note 2 | Mbps |
| | | | 2.7 V ≤ V _{DD} < 4.0 V | | | Note 3 | bps |
| | | | 2.3 V ≤ V _b ≤ 2.7 V | | | 1.2 Note 4 | Mbps |

Notes 1. The smaller maximum transfer rate derived by using fMCK/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ V_{DD} ≤ 5.5 V and 2.7 V ≤ V_b ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

2. This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 1 above to calculate the maximum transfer rate under conditions of the customer.

3. The smaller maximum transfer rate derived by using fMCK/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ V_{DD} < 4.0 V and 2.3 V ≤ V_b ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

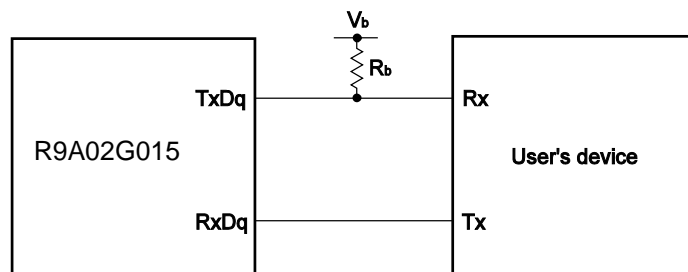
$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

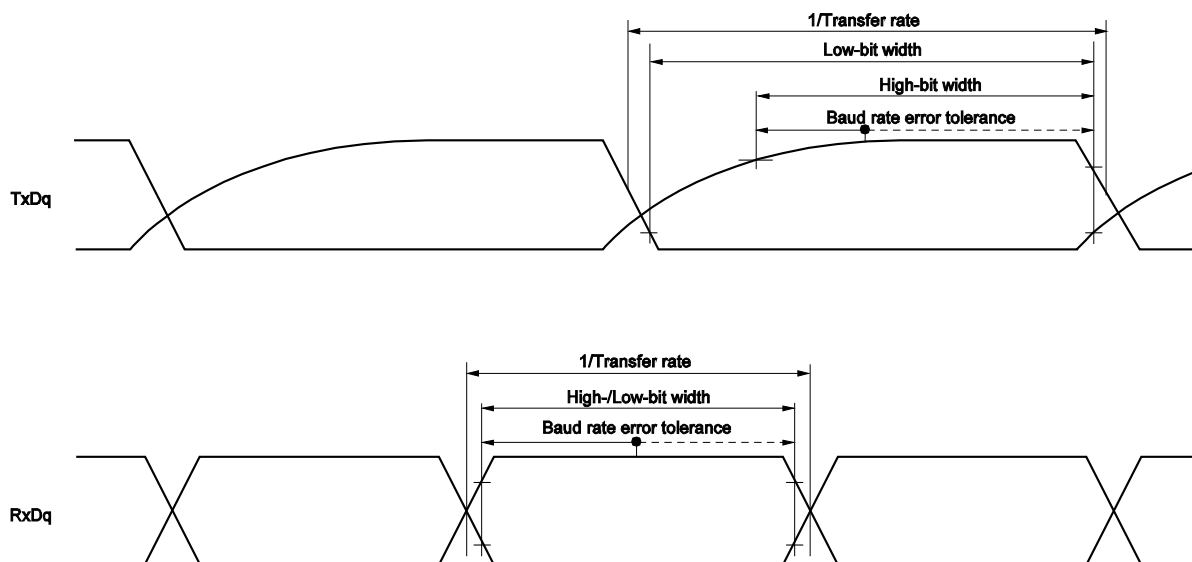
4. This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 3 above to calculate the maximum transfer rate under conditions of the customer.

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V_{DD} tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL} , see the DC characteristics with TTL input buffer selected.

UART mode connection diagram (during communication at different potential)



UART mode bit width (during communication at different potential) (reference)



- Remarks**
1. $R_b[\Omega]$: Communication line (TxDq) pull-up resistance, $C_b[F]$: Communication line (TxDq) load capacitance, $V_b[V]$: Communication line voltage
 2. q: UART number (q = 0), g: PIM and POM number (g = 5)
 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00))

(7) Communication at different potential (2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only)

(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|-------------------|--|----------------------------|------|------|------|
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 2/f _{CLK} 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 20 pF, R _b = 1.4 kΩ | 200 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 20 pF, R _b = 2.7 kΩ | 300 | | | ns |
| SCKp high-level width | t _{KH1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 20 pF, R _b = 1.4 kΩ | t _{KCY1} /2 - 50 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 20 pF, R _b = 2.7 kΩ | t _{KCY1} /2 - 120 | | | ns |
| SCKp low-level width | t _{KL1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 20 pF, R _b = 1.4 kΩ | t _{KCY1} /2 - 7 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 20 pF, R _b = 2.7 kΩ | t _{KCY1} /2 - 10 | | | ns |
| Slp setup time (to SCKp↑) ^{Note 1} | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 20 pF, R _b = 1.4 kΩ | 58 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 20 pF, R _b = 2.7 kΩ | 121 | | | ns |
| Slp hold time (from SCKp↑) ^{Note 1} | t _{KSH1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 20 pF, R _b = 1.4 kΩ | 10 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 20 pF, R _b = 2.7 kΩ | 10 | | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 1} | t _{KSO1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 20 pF, R _b = 1.4 kΩ | | | 60 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 20 pF, R _b = 2.7 kΩ | | | 130 | ns |
| Slp setup time (to SCKp↓) ^{Note 2} | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 20 pF, R _b = 1.4 kΩ | 23 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 20 pF, R _b = 2.7 kΩ | 33 | | | ns |
| Slp hold time (from SCKp↓) ^{Note 2} | t _{KSH1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 20 pF, R _b = 1.4 kΩ | 10 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 20 pF, R _b = 2.7 kΩ | 10 | | | ns |
| Delay time from SCKp↑ to SOp output ^{Note 2} | t _{KSO1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 20 pF, R _b = 1.4 kΩ | | | 10 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 20 pF, R _b = 2.7 kΩ | | | 10 | ns |

Notes 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

2. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

(Caution and Remark are listed on the next page.)

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL} , see the DC characteristics with TTL input buffer selected.

- Remarks**
1. $R_b[\Omega]$: Communication line (SCKp, SOp) pull-up resistance, $C_b[F]$: Communication line (SCKp, SOp) load capacitance, $V_b[V]$: Communication line voltage
 2. p: CSI number ($p = 00$), m: Unit number ($m = 0$), n: Channel number ($n = 0$),
g: PIM and POM number ($g = 5$)
 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,
n: Channel number ($mn = 00$))
 4. This value is valid only when CSI00's peripheral I/O redirect function is not used.

(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (1/2)
($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------|------------|---|--------------------|------|------|------|
| SCKp cycle time | t_{KCY1} | $t_{KCY1} \geq 4/f_{CLK}$ $4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$, $C_b = 30\text{ pF}$, $R_b = 1.4\text{ k}\Omega$ | 300 | | | ns |
| | | $2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$, $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$, $C_b = 30\text{ pF}$, $R_b = 2.7\text{ k}\Omega$ | 500 | | | ns |
| SCKp high-level width | t_{KH1} | $4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$, $C_b = 30\text{ pF}$, $R_b = 1.4\text{ k}\Omega$ | $t_{KCY1}/2 - 75$ | | | ns |
| | | $2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$, $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$, $C_b = 30\text{ pF}$, $R_b = 2.7\text{ k}\Omega$ | $t_{KCY1}/2 - 170$ | | | ns |
| SCKp low-level width | t_{KL1} | $4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$, $C_b = 30\text{ pF}$, $R_b = 1.4\text{ k}\Omega$ | $t_{KCY1}/2 - 12$ | | | ns |
| | | $2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$, $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$, $C_b = 30\text{ pF}$, $R_b = 2.7\text{ k}\Omega$ | $t_{KCY1}/2 - 18$ | | | ns |

- Cautions**
1. Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL} , see the DC characteristics with TTL input buffer selected.
 2. Use it with $V_{DD} \geq V_b$.

(Remarks are listed two pages after the next page.)

(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (2/2)
(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

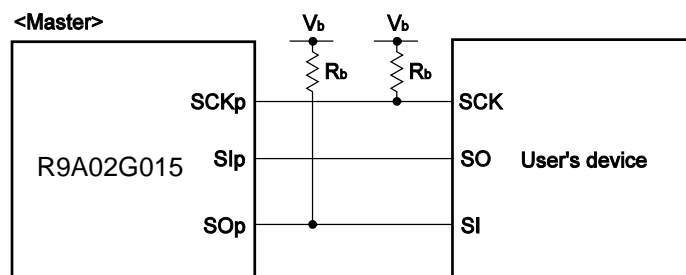
| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|-------------------|---|------|------|------|------|
| Slp setup time (to SCKp↑) ^{Note 1} | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 81 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 177 | | | ns |
| Slp hold time (from SCKp↑) ^{Note 1} | t _{KSH1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 19 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 19 | | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 1} | t _{KSO1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | | | 100 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | | | 195 | ns |
| Slp setup time (to SCKp↓) ^{Note 2} | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 44 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 44 | | | ns |
| Slp hold time (from SCKp↓) ^{Note 2} | t _{KSH1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 19 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 19 | | | ns |
| Delay time from SCKp↑ to SOp output ^{Note 2} | t _{KSO1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | | | 25 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | | | 25 | ns |

(Notes, Cautions and Remarks are listed on the next page.)

- Notes**
1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.
 2. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

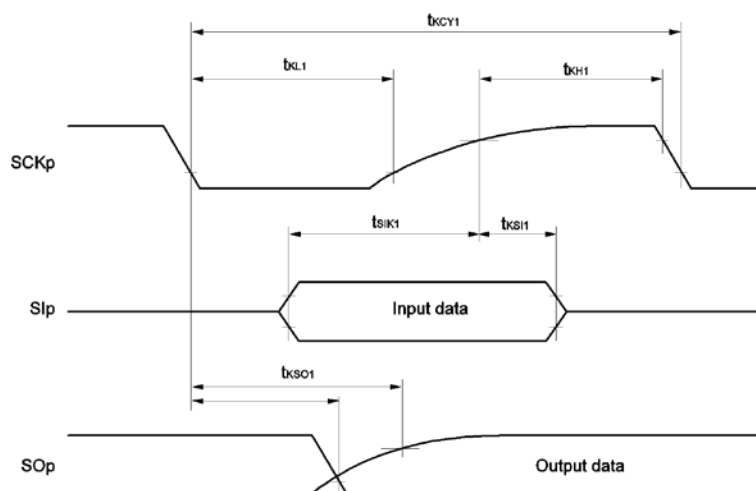
Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL} , see the DC characteristics with TTL input buffer selected.

CSI mode connection diagram (during communication at different potential)

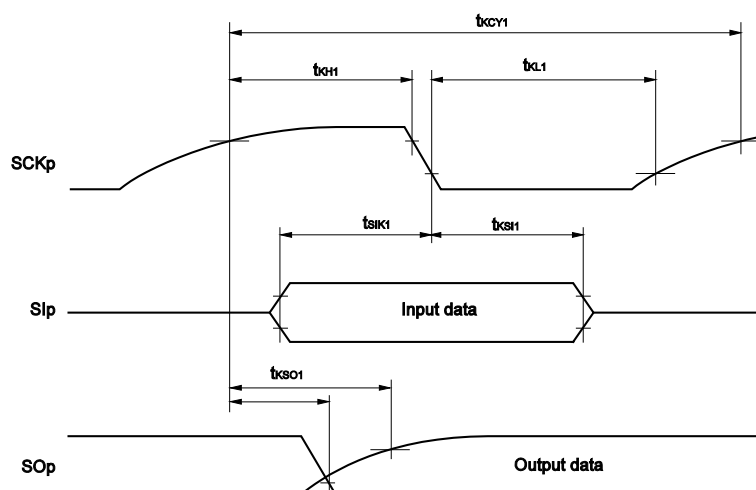


- Remarks**
1. $R_b[\Omega]$: Communication line (SCKp, SOp) pull-up resistance, $C_b[F]$: Communication line (SCKp, SOp) load capacitance, $V_b[V]$: Communication line voltage
 2. p: CSI number (p = 00), m: Unit number, n: Channel number (mn = 00), g: PIM and POM number (g = 5)
 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00))
 4. CSI01 cannot communicate at different potential. Use other CSI for communication at different potential.

CSI mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



CSI mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



- Remarks**
1. p: CSI number (p = 00), m: Unit number, n: Channel number (mn = 00), g: PIM and POM number (g = 5)
 2. CSI01 cannot communicate at different potential. Use other CSI for communication at different potential.

(9) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)
(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--|---|------------------------------------|---------------------|--------------------------|------|
| SCKp cycle time ^{Note 1} | t _{KCY2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | 20 MHz < f _{MCK} ≤ 24 MHz | 12/f _{MCK} | | ns |
| | | | 8 MHz < f _{MCK} ≤ 20 MHz | 10/f _{MCK} | | ns |
| | | | 4 MHz < f _{MCK} ≤ 8 MHz | 8/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 4 MHz | 6/f _{MCK} | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | 20 MHz < f _{MCK} ≤ 24 MHz | 16/f _{MCK} | | ns |
| | | | 16 MHz < f _{MCK} ≤ 20 MHz | 14/f _{MCK} | | ns |
| | | | 8 MHz < f _{MCK} ≤ 16 MHz | 12/f _{MCK} | | ns |
| | | | 4 MHz < f _{MCK} ≤ 8 MHz | 8/f _{MCK} | | ns |
| SCKp high-/low-level width | t _{KH2} , t _{KL2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | t _{KCY2} /2 – 12 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | t _{KCY2} /2 – 18 | | | ns |
| Slp setup time (to SCKp↑) ^{Note 2} | t _{SIK2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | 1/f _{MCK} + 20 | | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | 1/f _{MCK} + 20 | | | ns |
| Slp hold time (from SCKp↑) ^{Note 3} | t _{SI2} | | 1/f _{MCK} + 31 | | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 4} | t _{KSO2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | | | 2/f _{MCK} + 120 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | | | 2/f _{MCK} + 214 | ns |

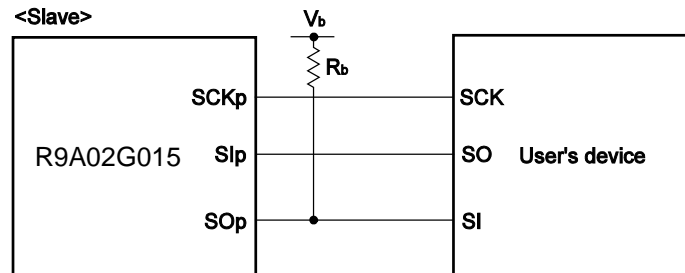
Notes 1. Transfer rate in the SNOOZE mode : MAX. 1 Mbps

2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
4. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

(Caution and Remarks are listed on the next page.)

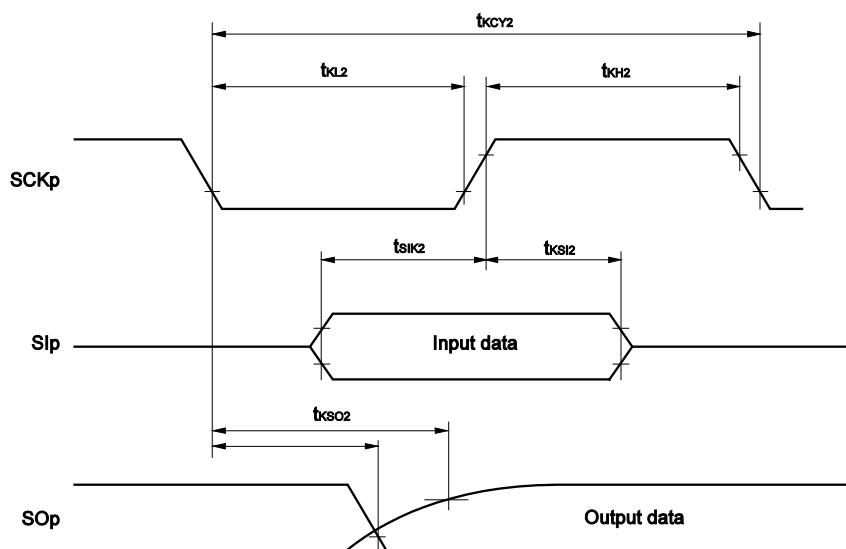
Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL} , see the DC characteristics with TTL input buffer selected.

CSI mode connection diagram (during communication at different potential)

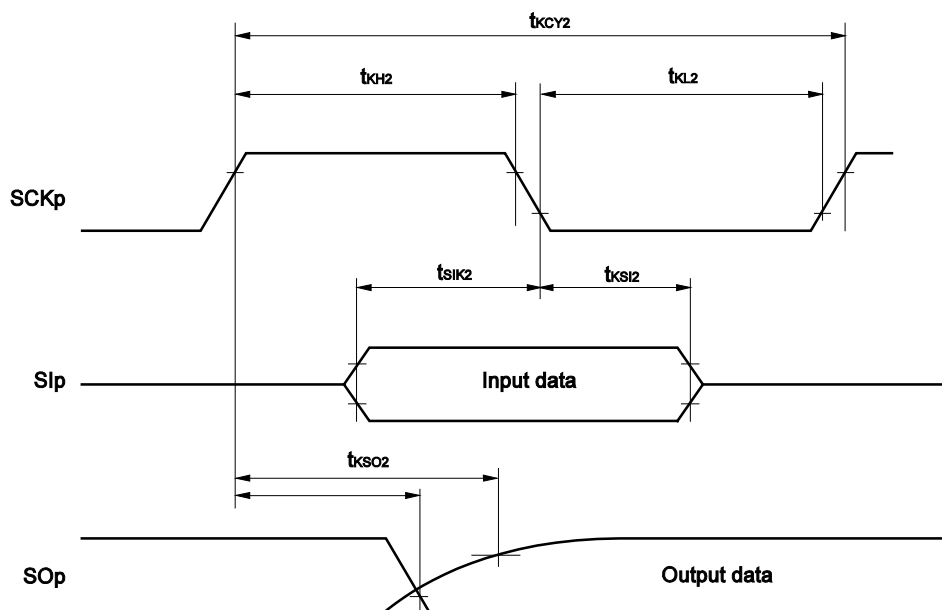


- Remarks**
1. $R_b[\Omega]$: Communication line (SO_p) pull-up resistance, $C_b[F]$: Communication line (SO_p) load capacitance, $V_b[V]$: Communication line voltage
 2. p: CSI number (p = 00), m: Unit number, n: Channel number (mn = 00), g: PIM and POM number (g = 5)
 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00))
 4. CSI01 cannot communicate at different potential. Use other CSI for communication at different potential.

CSI mode serial transfer timing (slave mode) (during communication at different potential)
 (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



CSI mode serial transfer timing (slave mode) (during communication at different potential)
 (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remarks 1. p: CSI number (p = 00), m: Unit number, n: Channel number (mn = 00),
 g: PIM and POM number (g = 5)

2. CSI01 cannot communicate at different potential. Use other CSI for communication at different potential.

(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode) (1/2)(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|---------------------------|-------------------|---|------|------------------------|------|
| SCLr clock frequency | f _{SCL} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | | 1000 ^{Note 1} | kHz |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | | 1000 ^{Note 1} | kHz |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | | 400 ^{Note 1} | kHz |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | | 400 ^{Note 1} | kHz |
| Hold time when SCLr = "L" | t _{LOW} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 475 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 475 | | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 1150 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 1150 | | ns |
| Hold time when SCLr = "H" | t _{HIGH} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 245 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 200 | | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 675 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 600 | | ns |

(Notes, Caution and Remarks are listed on the next page.)

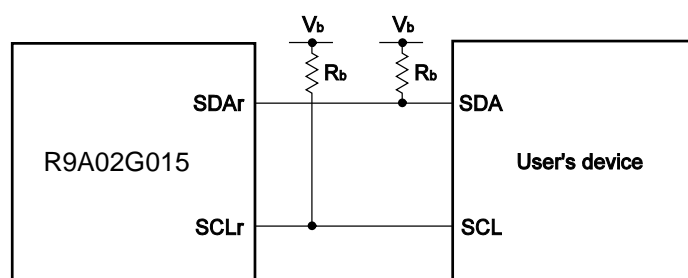
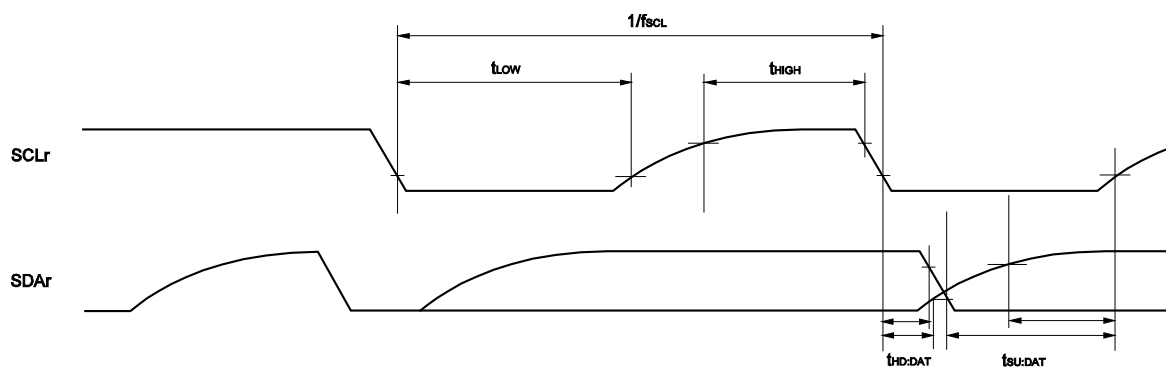
(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode) (2/2)**(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)**

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|-------------------------------|---------------------|---|------------------------------------|------|------|
| Data setup time (reception) | t _{SU:DAT} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 135 Note 2 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 135 Note 2 | | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 1/f _{MCK} + 190 Note 2 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 190 Note 2 | | ns |
| Data hold time (transmission) | t _{HD:DAT} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 0 | 305 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 0 | 305 | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 0 | 355 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b < 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 0 | 355 | ns |

Notes 1. The value must also be equal to or less than f_{MCK}/4.2. Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the TTL input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the N-ch open drain output (V_{DD} tolerance) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

Simplified I²C mode connection diagram (during communication at different potential)Simplified I²C mode serial transfer timing (during communication at different potential)

- Remarks**
1. $R_b[\Omega]$: Communication line (SDAr, SCLr) pull-up resistance, $C_b[F]$: Communication line (SDAr, SCLr) load capacitance, $V_b[V]$: Communication line voltage
 2. r: IIC number (r = 00), g: PIM, POM number (g = 5)
 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

2.5.2 Serial interface IICA

(1) I²C standard mode(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | Unit |
|---|---------------------|---|---------------------------------|---------------------------|------|------|
| | | | | MIN. | MAX. | |
| SCLA0 clock frequency | f _{SCL} | Standard mode: f _{CLK} ≥ 1 MHz | 2.7 V ≤ V _{DD} ≤ 5.5 V | 0 | 100 | kHz |
| Setup time of restart condition | t _{SU:STA} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 4.7 | | μs |
| Hold time ^{Note 1} | t _{HD:STA} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 4.0 | | μs |
| Hold time when SCLA0 = "L" | t _{LOW} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 4.7 | | μs |
| Hold time when SCLA0 = "H" | t _{HIGH} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 4.0 | | μs |
| Data setup time (reception) | t _{SU:DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 250 | | μs |
| Data hold time (transmission) ^{Note 2} | t _{HD:DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0 | 3.45 | μs |
| Setup time of stop condition | t _{SU:STO} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 4.0 | | μs |
| Bus-free time | t _{BUF} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 4.7 | | μs |

- Notes**
1. The first clock pulse is generated after this period when the start/restart condition is detected.
 2. The maximum value (MAX.) of t_{HD:DAT} is during normal transfer and a wait state is inserted in the $\overline{\text{ACK}}$ (acknowledge) timing.

Remark The maximum value of C_b (communication line capacitance) and the value of R_b (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode: C_b = 400 pF, R_b = 2.7 kΩ

(2) I²C fast mode(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | | HS (high-speed main) Mode | | Unit |
|---|---------------------|---------------------------------------|---------------------------------|---------------------------|------|------|
| | | | | MIN. | MAX. | |
| SCLA0 clock frequency | f _{SCL} | Fast mode: f _{CLK} ≥ 3.5 MHz | 2.7 V ≤ V _{DD} ≤ 5.5 V | 0 | 400 | kHz |
| Setup time of restart condition | t _{SU:STA} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.6 | | μs |
| Hold time ^{Note 1} | t _{HD:STA} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.6 | | μs |
| Hold time when SCLA0 = "L" | t _{LOW} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 1.3 | | μs |
| Hold time when SCLA0 = "H" | t _{HIGH} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.6 | | μs |
| Data setup time (reception) | t _{SU:DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 100 | | ns |
| Data hold time (transmission) ^{Note 2} | t _{HD:DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0 | 0.9 | μs |
| Setup time of stop condition | t _{SU:STO} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.6 | | μs |
| Bus-free time | t _{BUF} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 1.3 | | μs |

- Notes**
1. The first clock pulse is generated after this period when the start/restart condition is detected.
 2. The maximum value (MAX.) of t_{HD:DAT} is during normal transfer and a wait state is inserted in the $\overline{\text{ACK}}$ (acknowledge) timing.

Remark The maximum value of C_b (communication line capacitance) and the value of R_b (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode: C_b = 320 pF, R_b = 1.1 kΩ

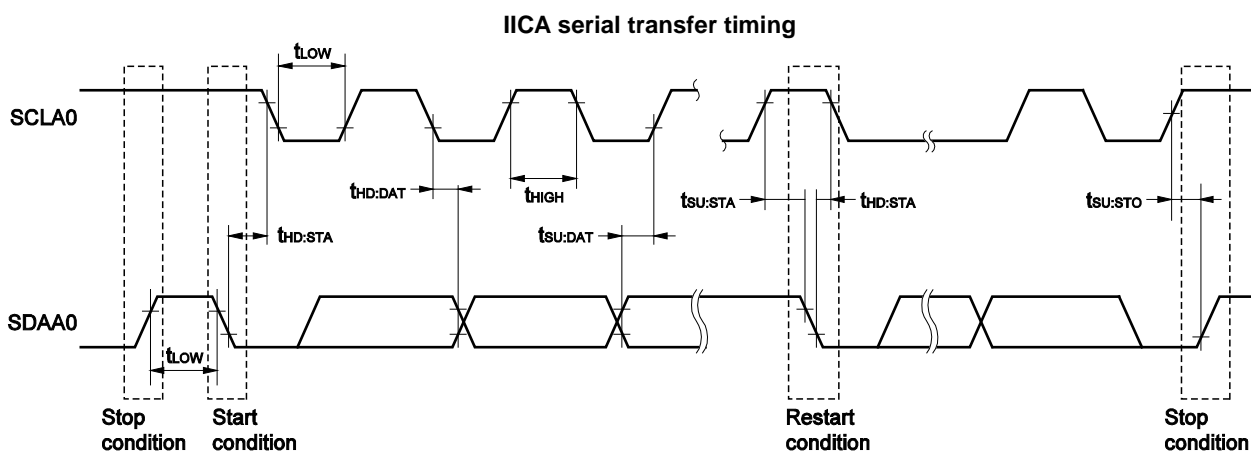
(3) I²C fast mode plus(T_A = -40 to +85°C, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | Symbol | Conditions | | HS (high-speed main) Mode | | Unit |
|---|---------------------|--|---------------------------------|---------------------------|------|------|
| | | | | MIN. | MAX. | |
| SCLA0 clock frequency | f _{SCL} | Fast mode plus: f _{CLK} ≥ 10 MHz | 2.7 V ≤ V _{DD} ≤ 5.5 V | 0 | 1000 | kHz |
| Setup time of restart condition | t _{SU:STA} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.26 | | μs |
| Hold time ^{Note 1} | t _{HD:STA} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.26 | | μs |
| Hold time when SCLA0 = "L" | t _{LOW} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.5 | | μs |
| Hold time when SCLA0 = "H" | t _{HIGH} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.26 | | μs |
| Data setup time (reception) | t _{SU:DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 50 | | ns |
| Data hold time (transmission) ^{Note 2} | t _{HD:DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0 | 0.45 | μs |
| Setup time of stop condition | t _{SU:STO} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.26 | | μs |
| Bus-free time | t _{BUF} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 0.5 | | μs |

- Notes**
1. The first clock pulse is generated after this period when the start/restart condition is detected.
 2. The maximum value (MAX.) of t_{HD:DAT} is during normal transfer and a wait state is inserted in the $\overline{\text{ACK}}$ (acknowledge) timing.

Remark The maximum value of C_b (communication line capacitance) and the value of R_b (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode plus: C_b = 120 pF, R_b = 1.1 kΩ



2.5.3 USB

(1) Electrical specifications

(T_A = -40 to +85°C, 3.0 V ≤ UV_{DD} ≤ 3.6 V, 3.0 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

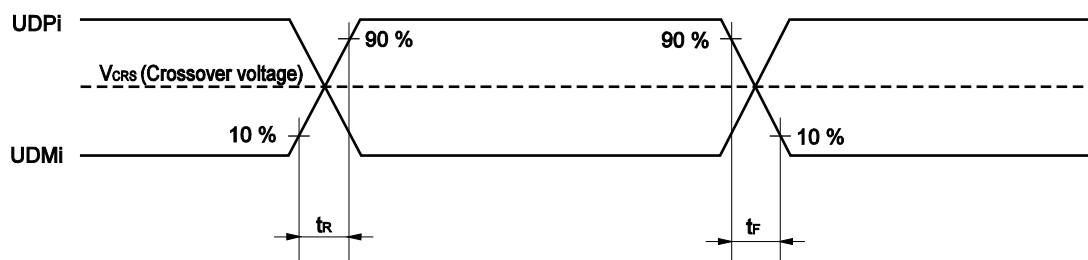
| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------|--|-------------------|---|---------------------------------|------|------|------|
| UV _{DD} | UV _{DD} input voltage characteristic | UV _{DD} | V _{DD} = 3.0 to 5.5 V, PXXCON = 1, VDDUSEB = 0 (UV _{DD} ≤ V _{DD}) | 3.0 | 3.3 | 3.6 | V |
| | UV _{DD} output voltage characteristic | UV _{DD} | V _{DD} = 4.0 to 5.5 V, PXXCON = VDDUSEB = 1 | 3.0 | 3.3 | 3.6 | V |
| UV _{BUS} | UV _{BUS} input voltage characteristic | UV _{BUS} | Function | 4.35 (4.02 ^{Note}) | 5.00 | 5.5 | V |
| | | | Host | 4.75 | 5.00 | 5.5 | V |

Note Value of instantaneous voltage(T_A = -40 to +85°C, 3.0 V ≤ UV_{DD} ≤ 3.6 V, 3.0 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|--------------------------------------|-------------------|--|-------|------|-------|------|
| UDPi/UDMi pins input characteristic | Input voltage | V _{IH} | | 2.0 | | | V |
| | | V _{IL} | | | | 0.8 | V |
| | Difference input sensitivity | V _{DI} | UDP voltage – UDM voltage | 0.2 | | | V |
| | Difference common mode range | V _{CM} | | 0.8 | | 2.5 | V |
| UDPi/UDMi pins output characteristic (FS driver) | Output voltage | V _{OH} | I _{OH} = -200 μA | 2.8 | | 3.6 | V |
| | | V _{OL} | I _{OL} = 2.4 mA | 0 | | 0.3 | V |
| | Transition time | t _{FR} | Rising: From 10% to 90 % of amplitude, | 4 | | 20 | ns |
| | | t _{FF} | Falling: From 90% to 10 % of amplitude, | 4 | | 20 | ns |
| | Matching (TFR/TFF) | T _{FRFM} | CL = 50 pF | 90 | | 111.1 | % |
| | Crossover voltage | V _{FCRS} | | 1.3 | | 2.0 | V |
| | Output Impedance | Z _{DRV} | UV _{DD} voltage = 3.3 V, Pin voltage = 1.65 V | 28 | | 44 | Ω |
| UDPi/UDMi pins pull-up, pull-down | Pull-down resistor | R _{PD} | | 14.25 | | 24.80 | kΩ |
| | Pull-up resistor (i = 0 only) | R _{PUI} | | 0.9 | | 1.575 | kΩ |
| | | R _{PUA} | | 1.425 | | 3.09 | kΩ |
| UV _{BUS} | UV _{BUS} pull-down resistor | R _{VBUS} | UV _{BUS} voltage = 5.5 V | | 1000 | | kΩ |
| | UV _{BUS} input voltage | V _{IH} | | 3.20 | | | V |
| | | V _{IL} | | | | 0.8 | V |

Remark i = 0, 1

Timing of UDPI and UDMi



(2) BC standard

($T_A = -40$ to $+85^\circ\text{C}$, $3.0\text{ V} \leq UV_{DD} \leq 3.6\text{ V}$, $3.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| | Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|----------------------------------|----------------|--|------|------|------|---------------|
| USB standard BC1.2 | UDPi sink current | I_{DP_SINK} | | 25 | | 175 | μA |
| | UDMi sink current | I_{DM_SINK} | | 25 | | 175 | μA |
| | Dedicated charging port resistor | R_{DCP_DAT} | $0\text{ V} < \text{UDP/UDM voltage} < 1.0\text{ V}$ | | | 200 | Ω |
| | Data detection voltage | V_{DAT_REF} | | 0.25 | | 0.4 | V |
| | UDPi source voltage | V_{DP_SRC} | Output current $250\text{ }\mu\text{A}$ | 0.5 | | 0.7 | V |
| | UDMi source voltage | V_{DM_SRC} | Output current $250\text{ }\mu\text{A}$ | 0.5 | | 0.7 | V |

Remark i = 0, 1

(3) BC option standard (Host)

(T_A = -40 to +85°C, 4.75 V ≤ UV_{BUS} ≤ 5.5 V, 3.0 V ≤ UV_{DD} ≤ 3.6 V, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|-----------------|------|-------------------------|--|------|------|-------|---------------------|
| UDPi output voltage (UV _{BUS} divider ratio) • VDOUE _i = 1 | VDSELi [3:0] | 1000 | V _{P20} | | 38 | 40 | 42 | % UV _{BUS} |
| | | 1001 | V _{P27} | | 51.6 | 53.6 | 55.6 | % UV _{BUS} |
| | | 1010 | V _{P20} | | 38 | 40 | 42 | % UV _{BUS} |
| | | 1100 | V _{P33} | | 60 | 66 | 72 | % UV _{BUS} |
| UDMi output voltage (UV _{BUS} divider ratio) • VDOUE _i = 1 | VDSELi [3:0] | 1000 | V _{M20} | | 38 | 40 | 42 | % UV _{BUS} |
| | | 1001 | V _{M20} | | 38 | 40 | 42 | % UV _{BUS} |
| | | 1010 | V _{M27} | | 51.6 | 53.6 | 55.6 | % UV _{BUS} |
| | | 1100 | V _{M33} | | 60 | 66 | 72 | % UV _{BUS} |
| UDPi comparing voltage Note 1 (UV _{BUS} divider ratio) • VDOUE _i = 1 • CUSDETE _i = 1 | VDSELi [3:0] | 1000 | V _{HDETP_UP0} | The rise of pin voltage detection voltage | 56.2 | | | % UV _{BUS} |
| | | | V _{HDETP_DWN0} | The fall of pin voltage detection voltage | | | 29.4 | % UV _{BUS} |
| | | 1001 | V _{HDETP_UP1} | The rise of pin voltage detection voltage | 60.5 | | | % UV _{BUS} |
| | | | V _{HDETP_DWN1} | The fall of pin voltage detection voltage | | | 45.0 | % UV _{BUS} |
| | | 1010 | V _{HDETP_UP2} | The rise of pin voltage detection voltage | 56.2 | | | % UV _{BUS} |
| | | | V _{HDETP_DWN2} | The fall of pin voltage detection voltage | | | 29.4 | % UV _{BUS} |
| UDMi comparing voltage Note 1 (UV _{BUS} divider ratio) • VDOUE _i = 1 • CUSDETE _i = 1 | VDSELi [3:0] | 1000 | V _{HDETM_UP0} | The rise of pin voltage detection voltage | 56.2 | | | % UV _{BUS} |
| | | | V _{HDETM_DWN0} | The fall of pin voltage detection voltage | | | 29.4 | % UV _{BUS} |
| | | 1001 | V _{HDETM_UP1} | The rise of pin voltage detection voltage | 56.2 | | | % UV _{BUS} |
| | | | V _{HDETM_DWN1} | The fall of pin voltage detection voltage | | | 29.4 | % UV _{BUS} |
| | | 1010 | V _{HDETM_UP2} | The rise of pin voltage detection voltage | 60.5 | | | % UV _{BUS} |
| | | | V _{HDETM_DWN2} | The fall of pin voltage detection voltage | | | 45.0 | % UV _{BUS} |
| UDPi pull-up detection Note 2 Connect detection with the full speed function (pull-up resistor) | | 1000 | R _{HDET_PULL} | In full-speed mode, the power supply voltage range of pull-up resistors connected to the USB function module is between 3.0 V and 3.6 V. | | | 1.575 | kΩ |
| | | 1001 | | | | | | |
| | | 1010 | | | | | | |
| UDMi pull-up detection Note 2 Connect detection with the low-speed (pull-up resistor) | | 1000 | R _{HDET_PULL} | In low-speed mode, the power supply voltage range of pull-up resistors connected to the USB function module is between 3.0 V and 3.6 V. | | | 1.575 | kΩ |
| | | 1001 | | | | | | |
| | | 1010 | | | | | | |
| UDMi sink current detection Note 2 Connect detection with the BC1.2 portable device (sink resistor) | | 1000 | I _{HDET_SINK} | | 25 | | | μA |
| | | 1001 | | | | | | |
| | | 1010 | | | | | | |

Notes 1. If the voltage output from UDPi or UDMi exceeds the range of the MAX and MIN values prescribed in this specification, DPCUSDETi (bit 8) and DMCUSDETi (bit 9) of the USBBCOPTi register are set to 1.

2. If the pull-up resistance or sink current prescribed in this specification is applied to UDPi or UDMi, DPCUSDETi (bit 8) and DMCUSDETi (bit 9) of the USBBCOPTi register are set to 1.

Remark i = 0, 1

(4) BC option standard (Function)

(T_A = -40 to +85°C, 4.35 V ≤ UV_{BUS} ≤ 5.5 V, 3.0 V ≤ UV_{DD} ≤ 3.6 V, 2.7 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|-----------------|------|---------------------|------------|------|------|------|---------------------|
| UDPi/UDMi input reference voltage (UV _{BUS} divider ratio) • VDOUE _i = 0 | VDSELi [3:0] | 0000 | V _{DDET0} | | 27 | 32 | 37 | % UV _{BUS} |
| | | 0001 | V _{DDET1} | | 29 | 34 | 39 | % UV _{BUS} |
| | | 0010 | V _{DDET2} | | 32 | 37 | 42 | % UV _{BUS} |
| | | 0011 | V _{DDET3} | | 35 | 40 | 45 | % UV _{BUS} |
| | | 0100 | V _{DDET4} | | 38 | 43 | 48 | % UV _{BUS} |
| | | 0101 | V _{DDET5} | | 41 | 46 | 51 | % UV _{BUS} |
| | | 0110 | V _{DDET6} | | 44 | 49 | 54 | % UV _{BUS} |
| | | 0111 | V _{DDET7} | | 47 | 52 | 57 | % UV _{BUS} |
| | | 1000 | V _{DDET8} | | 51 | 56 | 61 | % UV _{BUS} |
| | | 1001 | V _{DDET9} | | 55 | 60 | 65 | % UV _{BUS} |
| | | 1010 | V _{DDET10} | | 59 | 64 | 69 | % UV _{BUS} |
| | | 1011 | V _{DDET11} | | 63 | 68 | 73 | % UV _{BUS} |
| | | 1100 | V _{DDET12} | | 67 | 72 | 77 | % UV _{BUS} |
| | | 1101 | V _{DDET13} | | 71 | 76 | 81 | % UV _{BUS} |
| | | 1110 | V _{DDET14} | | 75 | 80 | 85 | % UV _{BUS} |
| | | 1111 | V _{DDET15} | | 79 | 84 | 89 | % UV _{BUS} |

Remark i = 0, 1

2.6 Analog Characteristics

2.6.1 A/D converter characteristics

Classification of A/D converter characteristics

| Input channel | Reference Voltage | | |
|--|--|--|--|
| | Reference voltage (+) = AV_{REFP} Reference voltage (-) = AV_{REFM} | Reference voltage (+) = V_{DD} Reference voltage (-) = V_{SS} | Reference voltage (+) = V_{BGR} Reference voltage (-) = AV_{REFM} |
| ANI0 to ANI5 | Refer to 2.6.1 (1). | Refer to 2.6.1 (3). | Refer to 2.6.1 (4). |
| ANI16, ANI17 | Refer to 2.6.1 (2). | | |
| Internal reference voltage Temperature sensor output voltage | Refer to 2.6.1 (1). | | — |

(1) When $AV_{REF} (+) = AV_{REFP}/ANI0$ ($ADREFP1 = 0$, $ADREFP0 = 1$), reference voltage (-) = $AV_{REFM}/ANI1$ ($ADREFM = 1$), target pin : ANI2 to ANI5, internal reference voltage, and temperature sensor output voltage

($T_A = -40$ to $+85^{\circ}\text{C}$, $2.7\text{ V} \leq AV_{REFP} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$, Reference voltage (+) = AV_{REFP} , Reference voltage (-) = $AV_{REFM} = 0\text{ V}$)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|---------------------------------|-----------|--|--|--------------------------------|------|-------------|------|
| Resolution | RES | | | 8 | | 10 | bit |
| Overall error ^{Note 1} | $AINL$ | 10-bit resolution $AV_{REFP} = V_{DD}$ ^{Note 2} | $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | | 1.2 | ± 3.5 | LSB |
| Analog input voltage | V_{AIN} | ANI2 to ANI7 | | 0 | | AV_{REFP} | V |
| | | Internal reference voltage ($2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, HS (high-speed main) mode) | | V_{BGR} ^{Note 3} | | | V |
| | | Temperature sensor output voltage ($2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, HS (high-speed main) mode) | | V_{TMPS25} ^{Note 3} | | | V |

Notes 1. Excludes quantization error ($\pm 1/2$ LSB).

2. When $AV_{REFP} < V_{DD}$, the MAX. values are as follows.

Overall error: Add ± 1.0 LSB to the MAX. value when $AV_{REFP} = V_{DD}$.

3. Refer to 2.6.2 Temperature sensor/internal reference voltage characteristics.

(2) When reference voltage (+) = $AV_{REFP}/ANI0$ ($ADREFP1 = 0$, $ADREFP0 = 1$), reference voltage (–) = $AV_{REFM}/ANI1$ ($ADREFM = 1$), target pin : ANI16, ANI17

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq AV_{REFP} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$, Reference voltage (+) = AV_{REFP} , Reference voltage (–) = $AV_{REFM} = 0\text{ V}$)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|---------------------------------|-----------|---|--|------|------|-----------------------------|------|
| Resolution | R_{ES} | | | 8 | | 10 | bit |
| Overall error ^{Note 1} | A_{INL} | 10-bit resolution $AV_{REFP} = V_{DD}$ ^{Note 2} | $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | | 1.2 | ± 5.0 | LSB |
| Analog input voltage | V_{AIN} | ANI16, ANI17 | | 0 | | AV_{REFP} and V_{DD} | V |

Notes 1. Excludes quantization error ($\pm 1/2$ LSB).

2. When $AV_{REFP} < V_{DD}$, the MAX. values are as follows.

Overall error: Add ± 4.0 LSB to the MAX. value when $AV_{REFP} = V_{DD}$.

(3) Reference voltage (+) = V_{DD} ($ADREFP1 = 0$, $ADREFP0 = 0$), Reference voltage (–) = V_{SS} ($ADREFM = 0$), target ANI pin : ANI0 to ANI5, ANI16, ANI17, internal reference voltage, and temperature sensor output voltage

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$, Reference voltage (+) = V_{DD} , Reference voltage (–) = V_{SS})

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|---------------------------------|-----------|--|--|--------------------------------|------|-----------|------|
| Resolution | R_{ES} | | | 8 | | 10 | bit |
| Overall error ^{Note 1} | A_{INL} | 10-bit resolution | $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | | 1.2 | ± 7.0 | LSB |
| Analog input voltage | V_{AIN} | ANI0 to ANI5, ANI16, ANI17 | | 0 | | V_{DD} | V |
| | | Internal reference voltage ($2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, HS (high-speed main) mode) | | V_{BGR} ^{Note 2} | | | V |
| | | Temperature sensor output voltage ($2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, HS (high-speed main) mode) | | V_{TMPS25} ^{Note 2} | | | V |

Notes 1. Excludes quantization error ($\pm 1/2$ LSB).

2. Refer to 2.6.2 Temperature sensor/internal reference voltage characteristics.

(4) When Reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), Reference voltage (–) = $AV_{REFM}/ANI1$ (ADREFM = 1), target pin : ANI0 to ANI5, ANI16, ANI17

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$, Reference voltage (+) = V_{BGR} ^{Note 1}, Reference voltage (–) = $AV_{REFM} = 0\text{ V}$, HS (high-speed main) mode)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------|-----------|------------|------|------|-----------------------------|------|
| Resolution | R_{ES} | | 8 | | | Bit |
| Analog input voltage | V_{AIN} | | 0 | | V_{BGR} ^{Note 1} | V |

Notes 1. Refer to 2.6.2 Temperature sensor/internal reference voltage characteristics.

2.6.2 Temperature sensor/internal reference voltage characteristics

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$, HS (high-speed main) mode)

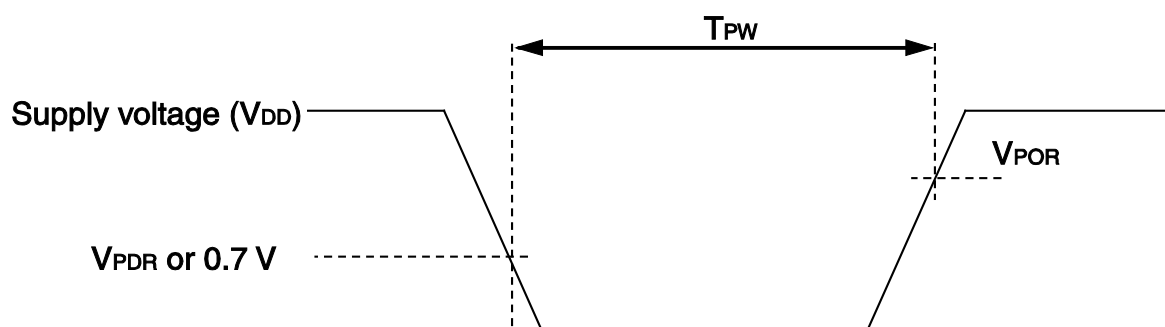
| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------------|--------------|---|------|------|------|----------------------|
| Temperature sensor output voltage | V_{TMPS25} | Setting ADS register = 80H, $T_A = +25^\circ\text{C}$ | | 1.05 | | V |
| Internal reference voltage | V_{BGR} | Setting ADS register = 81H | 1.38 | 1.45 | 1.5 | V |
| Temperature coefficient | F_{VTMPS} | Temperature sensor that depends on the temperature | | -3.6 | | mV/ $^\circ\text{C}$ |
| Operation stabilization wait time | t_{AMP} | | 5 | | | μs |

2.6.3 POR circuit characteristics

($T_A = -40$ to $+85^\circ\text{C}$, $V_{SS} = 0\text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|-----------|------------------------|------|------|------|---------------|
| Detection voltage | V_{POR} | Power supply rise time | 1.47 | 1.51 | 1.55 | V |
| | V_{PDR} | Power supply fall time | 1.46 | 1.50 | 1.54 | V |
| Minimum pulse width ^{Note} | T_{PW} | | 300 | | | μs |

Note Minimum time required for a POR reset when V_{DD} exceeds below V_{PDR} . This is also the minimum time required for a POR reset from when V_{DD} exceeds below 0.7 V to when V_{DD} exceeds V_{POR} while STOP mode is entered or the main system clock (f_{MAIN}) is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



2.6.4 LVD circuit characteristics

LVD Detection Voltage of Reset Mode and Interrupt Mode

($T_A = -40$ to $+85^\circ\text{C}$, $V_{PDR} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------|----------------------|-------------------|------------------------|------|------|------|------|
| Detection voltage | Supply voltage level | V _{LVD0} | Power supply rise time | 3.98 | 4.06 | 4.14 | V |
| | | | Power supply fall time | 3.90 | 3.98 | 4.06 | V |
| | | V _{LVD1} | Power supply rise time | 3.68 | 3.75 | 3.82 | V |
| | | | Power supply fall time | 3.60 | 3.67 | 3.74 | V |
| | | V _{LVD2} | Power supply rise time | 3.07 | 3.13 | 3.19 | V |
| | | | Power supply fall time | 3.00 | 3.06 | 3.12 | V |
| | | V _{LVD3} | Power supply rise time | 2.96 | 3.02 | 3.08 | V |
| | | | Power supply fall time | 2.90 | 2.96 | 3.02 | V |
| | | V _{LVD4} | Power supply rise time | 2.86 | 2.92 | 2.97 | V |
| | | | Power supply fall time | 2.80 | 2.86 | 2.91 | V |
| | | V _{LVD5} | Power supply rise time | 2.76 | 2.81 | 2.87 | V |
| | | | Power supply fall time | 2.70 | 2.75 | 2.81 | V |
| Minimum pulse width | | t _{LW} | | 300 | | | μs |
| Detection delay time | | t _{LD} | | | | 300 | μs |

LVD Detection Voltage of Interrupt & Reset Mode

($T_A = -40$ to $+85^\circ\text{C}$, $V_{PDR} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit | |
|--------------------------|--------------------|--|---------------------|------------------------------|------|------|------|---|
| Interrupt and reset mode | V _{LVDC0} | VPOC2, VPOC1, VPOC0 = 0, 1, 0, falling reset voltage | | 2.40 | 2.45 | 2.50 | V | |
| | V _{LVDC1} | | LVIS1, LVIS0 = 1, 0 | Rising release reset voltage | 2.56 | 2.61 | 2.66 | V |
| | | | | Falling interrupt voltage | 2.50 | 2.55 | 2.60 | V |
| | V _{LVDC2} | | LVIS1, LVIS0 = 0, 1 | Rising release reset voltage | 2.66 | 2.71 | 2.76 | V |
| | | | | Falling interrupt voltage | 2.60 | 2.65 | 2.70 | V |
| | V _{LVDC3} | | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 3.68 | 3.75 | 3.82 | V |
| | | Falling interrupt voltage | | 3.60 | 3.67 | 3.74 | V | |
| | V _{LVDD0} | VPOC2, VPOC1, VPOC0 = 0, 1, 1, falling reset voltage | | 2.70 | 2.75 | 2.81 | V | |
| | V _{LVDD1} | | LVIS1, LVIS0 = 1, 0 | Rising release reset voltage | 2.86 | 2.92 | 2.97 | V |
| | | | | Falling interrupt voltage | 2.80 | 2.86 | 2.91 | V |
| | V _{LVDD2} | | LVIS1, LVIS0 = 0, 1 | Rising release reset voltage | 2.96 | 3.02 | 3.08 | V |
| | | | | Falling interrupt voltage | 2.90 | 2.96 | 3.02 | V |
| | V _{LVDD3} | | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 3.98 | 4.06 | 4.14 | V |
| | | | | Falling interrupt voltage | 3.90 | 3.98 | 4.06 | V |

2.6.5 Power supply voltage rising slope characteristics

($T_A = -40$ to $+85^\circ\text{C}$, $V_{SS} = 0\text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------------|-----------|------------|------|------|------|------|
| Power supply voltage rising slope | S_{VDD} | | | | 54 | V/ms |

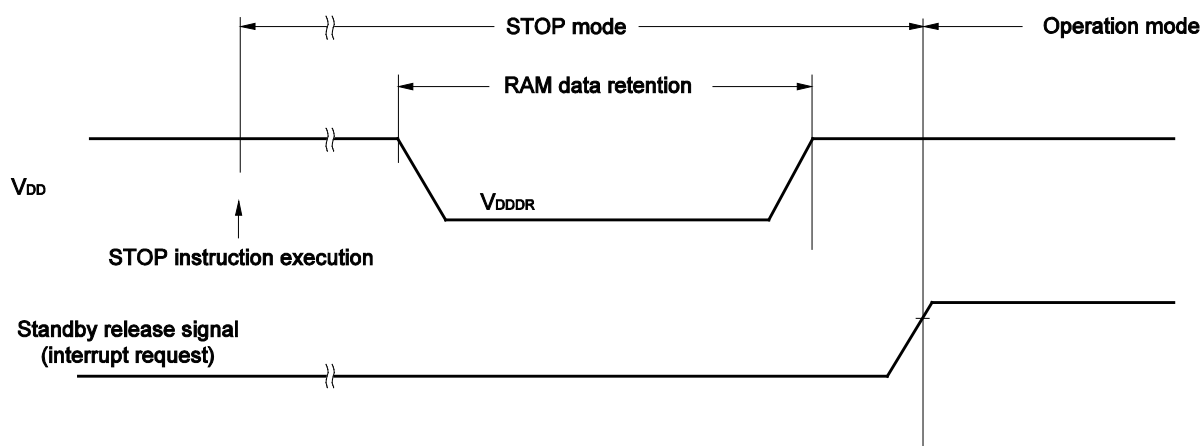
Caution Make sure to keep the internal reset state by the LVD circuit or an external reset until V_{DD} reaches the operating voltage range shown in 2.4 AC Characteristics.

2.7 RAM Data Retention Characteristics

($T_A = -40$ to $+85^\circ\text{C}$, $V_{SS} = 0\text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------|------------|------------|----------------------|------|------|------|
| Data retention supply voltage | V_{DDDR} | | 1.46 ^{Note} | | 5.5 | V |

Note The value depends on the POR detection voltage. When the voltage drops, the data is retained before a POR reset is effected, but data is not retained when a POR reset is effected.



2.8 Flash Memory Programming Characteristics

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|-------------------|---|---------|-----------|------|-------|
| CPU/peripheral hardware clock frequency | f _{CLK} | 2.7 V ≤ V _{DD} ≤ 5.5 V | 1 | | 24 | MHz |
| Number of code flash rewrites | C _{erwr} | Retaining years: 20 years T _A = +85°C | 1,000 | | | Times |
| Number of data flash rewrites Notes 1, 2, 3 | | Retaining years: 1 year T _A = +25°C | | 1,000,000 | | |
| | | Retaining years: 5 years T _A = +85°C | 100,000 | | | |
| | | Retaining years: 20 years T _A = +85°C | 10,000 | | | |

Notes 1. 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.

2. When using flash memory programmer and Renesas Electronics self programming library.

3. These specifications show the characteristics of the flash memory and the results obtained from Renesas Electronics reliability testing.

2.9 Dedicated Flash Memory Programmer Communication (UART)

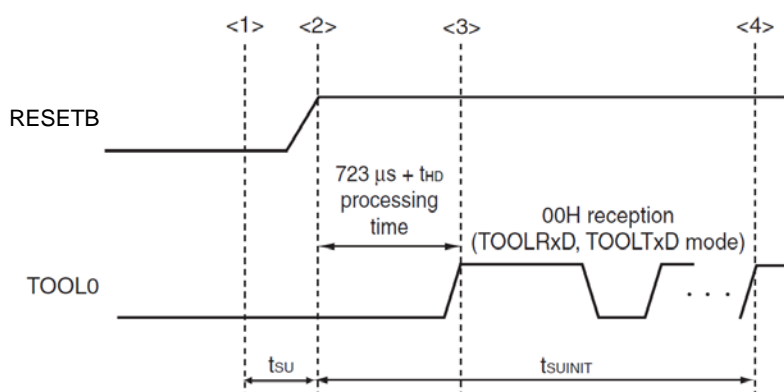
($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------|--------|---------------------------|---------|------|-----------|------|
| Transfer rate | | During serial programming | 115,200 | | 1,000,000 | bps |

2.10 Timing Specs for Switching Flash Memory Programming Modes

($T_A = -40$ to $+85^\circ\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $V_{SS} = 0\text{ V}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--------------------|--|------|------|------|---------------|
| How long from when an external reset ends until the initial communication settings are specified | t_{SUNIT} | POR and LVD reset must end before the external reset ends. | | | 100 | ms |
| How long from when the TOOL0 pin is placed at the low level until an external reset ends | t_{SU} | POR and LVD reset must end before the external reset ends. | 10 | | | μs |
| How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory) | t_{HD} | POR and LVD reset must end before the external reset ends. | 1 | | | ms |



<1> The low level is input to the TOOL0 pin.

<2> The external reset ends (POR and LVD reset must end before the external reset ends.).

<3> The TOOL0 pin is set to the high level.

<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

Remark t_{SUNIT} : The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the resets end.

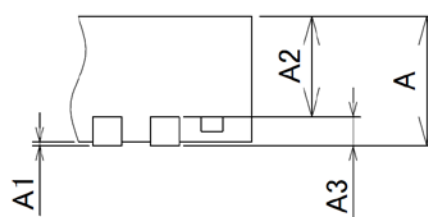
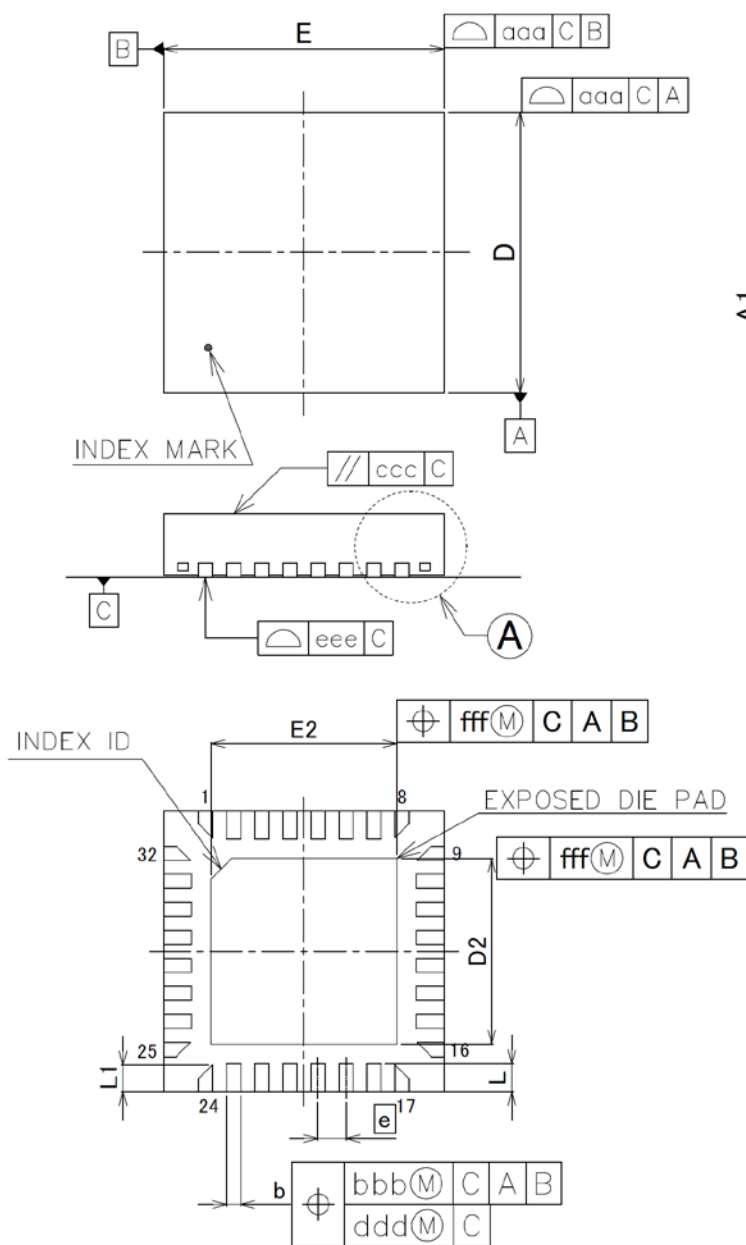
t_{SU} : How long from when the TOOL0 pin is placed at the low level until an external reset ends

t_{HD} : How long to keep the TOOL0 pin at the low level from when the external and internal resets end (excluding the processing time of the firmware to control the flash memory)

3. PACKAGE DRAWINGS

32-pin QFN (4 x 4 mm)

| JEITA Package Code | RENESAS Code | MASS (Typ.) [g] |
|----------------------|--------------|------------------|
| P-HVQFN32-4 × 4-0.40 | PVQN0032LD-A | 0.04 |



| Reference Symbol | Dimension in Millimeters | | |
|------------------|--------------------------|-------|-------|
| | Min. | Nom. | Max. |
| A | — | — | 0.900 |
| A1 | — | — | 0.050 |
| A2 | — | 0.650 | 0.700 |
| A3 | — | 0.203 | — |
| b | 0.150 | — | 0.250 |
| D | — | 4 | — |
| D2 | — | 2.650 | — |
| E | — | 4 | — |
| E2 | — | 2.650 | — |
| L | 0.350 | 0.400 | 0.450 |
| L1 | 0.307 | 0.382 | 0.407 |
| e | — | 0.400 | — |
| aaa | — | — | 0.100 |
| bbb | — | — | 0.100 |
| ccc | — | — | 0.100 |
| ddd | — | — | 0.050 |
| eee | — | — | 0.050 |
| fff | — | — | 0.100 |

| | |
|------------------|----------------------|
| Revision History | R9A02G015 Data Sheet |
|------------------|----------------------|

| Rev. | Date | Description | |
|------|--------------|-------------|---|
| | | Page | Summary |
| 0.10 | Oct 31, 2018 | — | First Draft of the Preliminary Data Sheet |
| 0.20 | Nov 9, 2018 | 15 | Updated section 2.3.2 |
| | | 44-45 | Updated section 2.5.3 |
| 0.90 | Feb 15, 2019 | 15 | Updated section 2.3.2 |
| | | 42-43 | Updated section 2.5.3 |
| | | 53 | Updated section 3 |
| 1.00 | Mar 29, 2019 | — | First Edition issued. |

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